

Vth Sesame meeting – Alexandria 27-29 November 2006

**Nano-scale chemical mapping and  
surface structural modification  
by joint use of  
X-ray microbeams  
and tip assisted local detection**

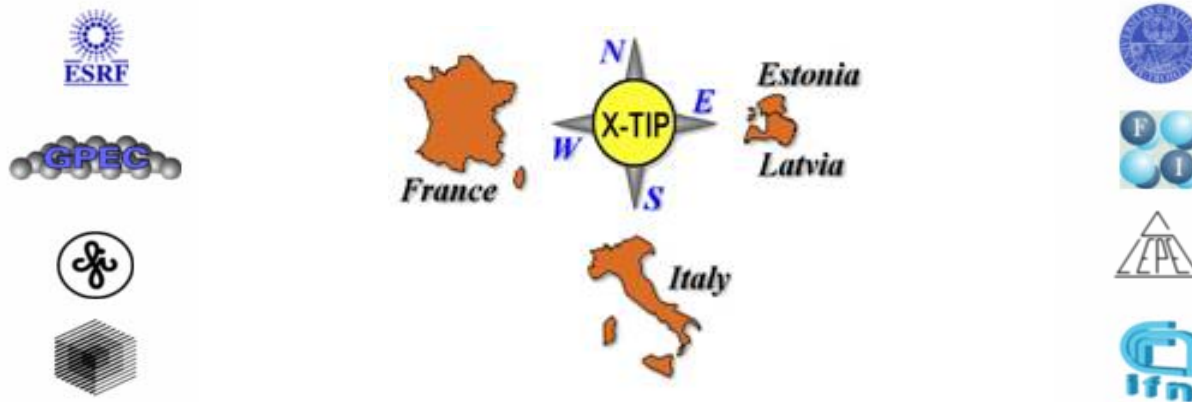
*Giuseppe Dalba*  
University of Trento  
Italy

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# Outline

- **Introduction**  
X-TIP Project: goals and scientific research program
  - **X-ray Absorption Fine Spectroscopy**  
The measurement technical modes  
Chemical-Physical information
  - **Scanning Probe Microscopy (SPM)**  
Scanning Tunnelling Microscopy (STM)  
Atomic Force Microscopy (AFM)  
Scanning Near Field Microscopy (SNOM)
  - **X-tip project: some results**  
X-tip measurements  
XEOL measurements
  - **Conclusions**
-

# X-TIP Project Aims



Specific Targeted Research Project (STRP)  
Supported by European Commission 6<sup>th</sup> Framework Programme

Budget: 1.1 million Euro

to deliver instrumentation and techniques  
that merge the ability of Synchrotron Radiation spectroscopies  
in providing elemental composition, chemical status and  
structural information  
with the lateral resolution of  
Local Probe Microscopes in providing detailed surface morphology

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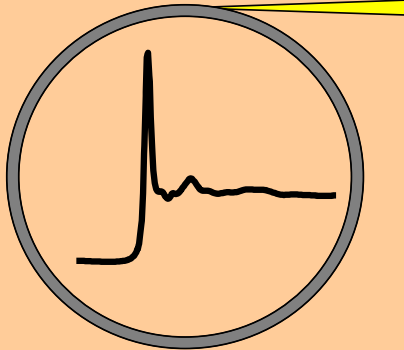
# Objectives of the X-tip project

• **XAS-TEY** - Element-Specific Contrast in Local Probe Microscopy via X-Ray excited photoelectrons detection by conductive tip in Total Electron Yield collection mode [TEY].

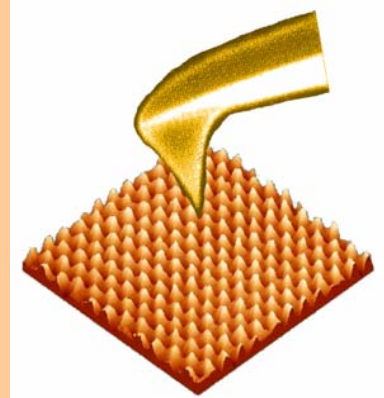
• **XAS-SNOM** - Element-Specific Contrast in Local Probe Microscopy via X-Ray Excited Optical Luminescence (XEOL) detection by optical probe in SNOM mode.

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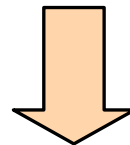
# Objectives of the X-tip project



**X-Ray Absorption  
Spectroscopy using  
Synchrotron Radiation**



**Scanning Probe Microscopy**

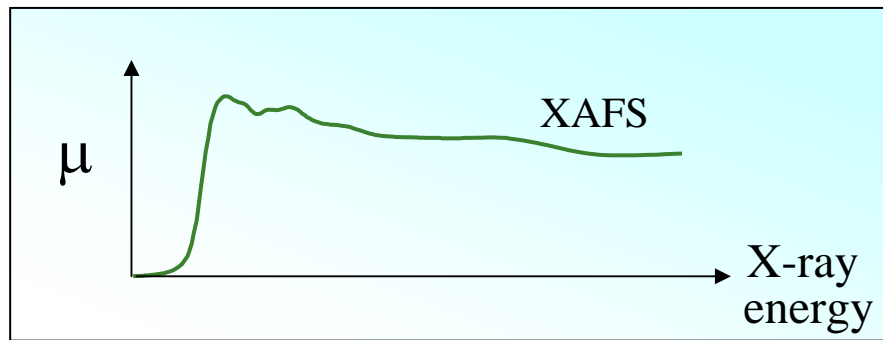
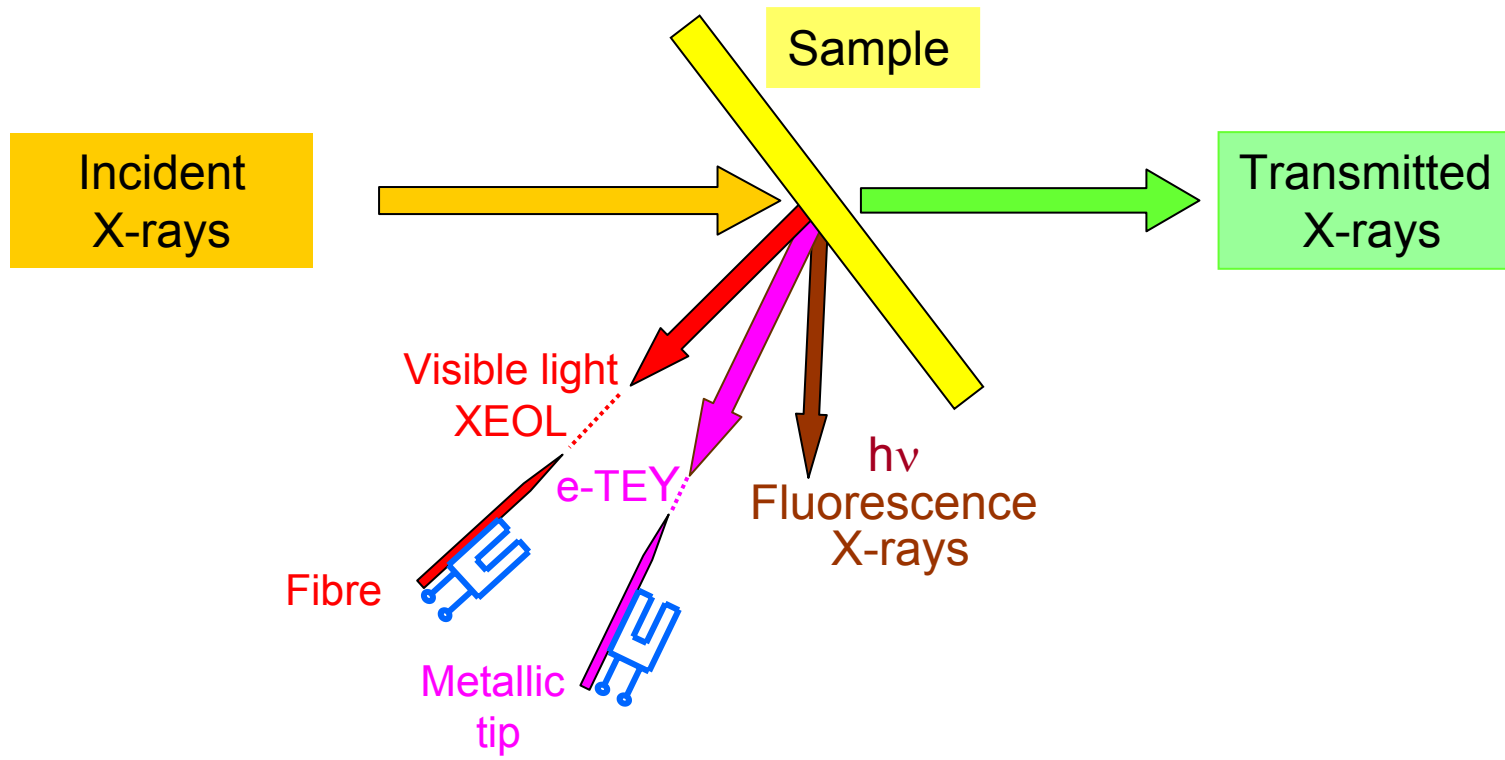


**Combined Nano-Scale Spectro-Microscopy**

able to provide Mapping and Physico-Chemical characterization of nanostructures

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# X-ray Absorption Spectroscopy (XAS)



# Info from X-ray Absorption Spectroscopy

**Type of atom** surrounding the central absorber atom (typically  $\Delta Z > \pm 2$ )

**Number of atoms** surrounding the absorber atom ( $\pm 5 \div 20\%$ )

**Interatomic distance** ( $\pm 0.01 \text{ \AA}$  for the 1<sup>o</sup> coordination shell)

**Atomic disorder** (from Debye-Waller term)

**Oxidation state** of the absorbing atom

**Ligand geometry** (from intra-ligand multiple scattering)

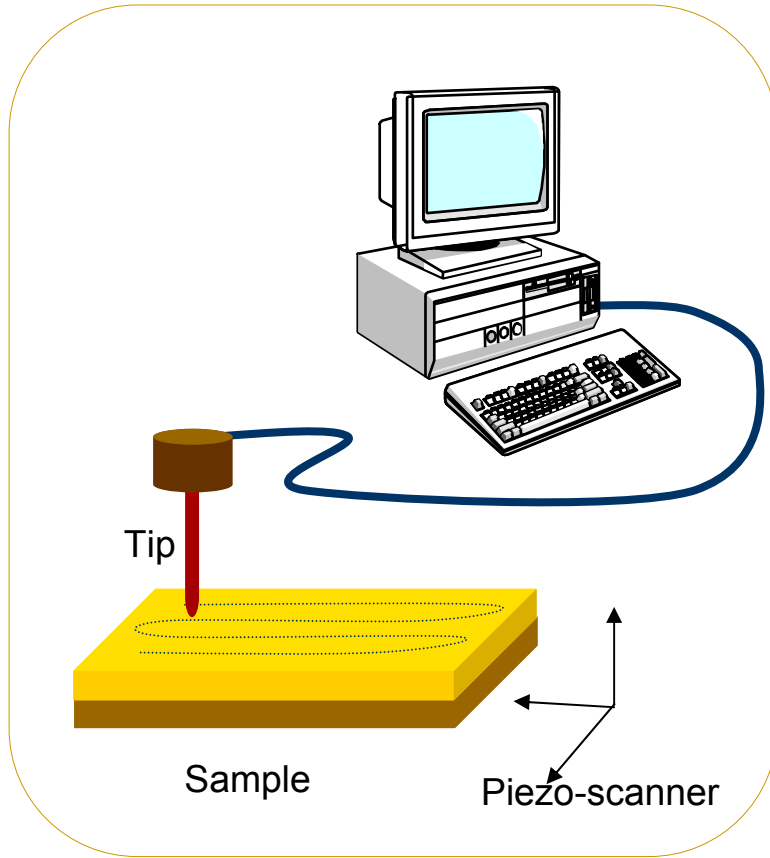
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# Outline

- **Introduction**
    - X-TIP Project: goals and scientific research program
  - **X-ray Absorption Fine Spectroscopy**
    - The measurement technical modes modes
    - Chemical-Physical information
  - **Scanning Probe Microscopy (SPM)**
    - Scanning Tunneling Microscopy (STM)
    - Atomic Force Microscopy (AFM)
    - Scanning Near Field Microscopy (SNOM)
  - **First results**
    - X-tip measurements
    - XEOL measurements
  - **Conclusions**
-



# SPM: Scanning Probe Microscopy



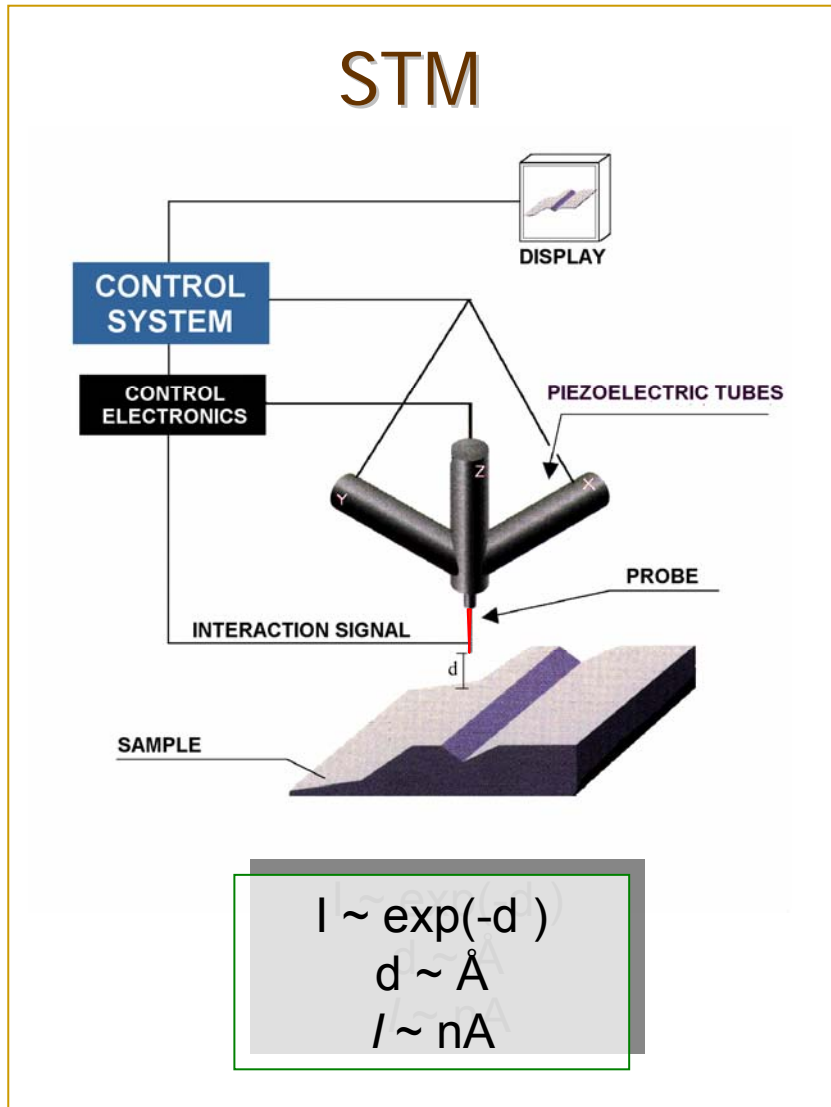
Surface image

## Components

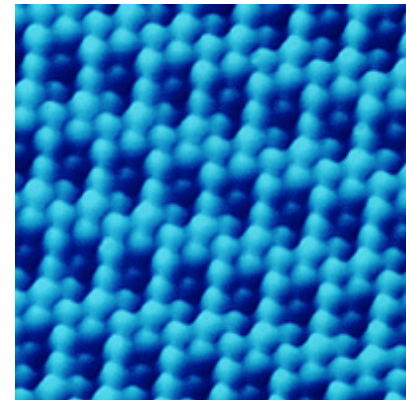
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data

Recorded sound

# Scanning Tunnelling Microscopy (STM)



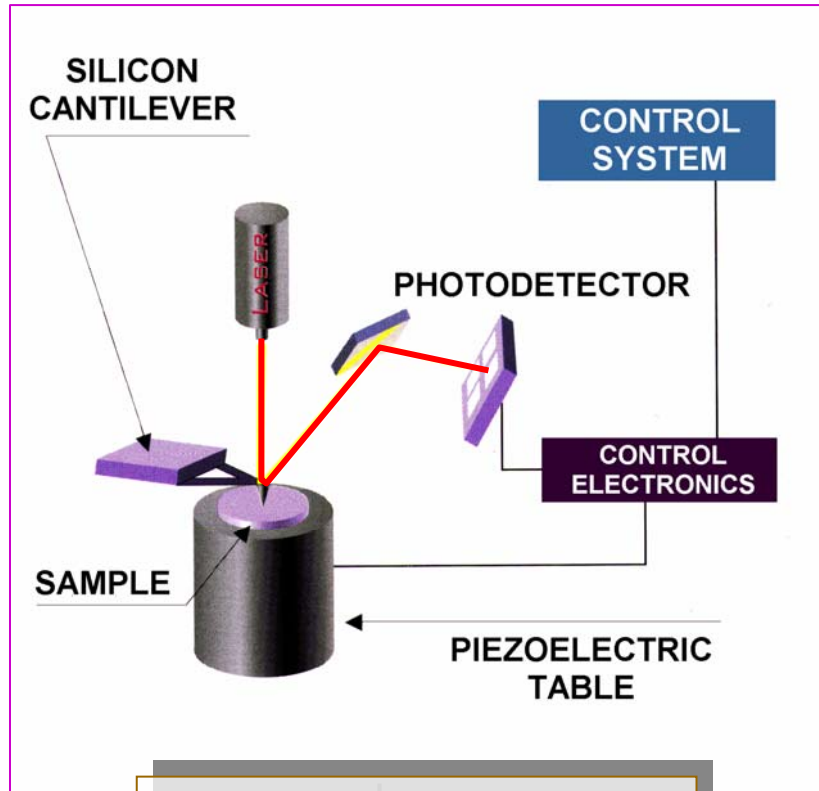
Only conductive materials



STM image of a crystal surface : single molecule resolution

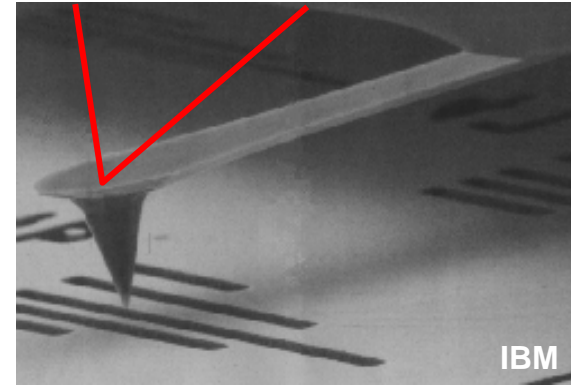
# Atomic Force Microscopy

## AFM



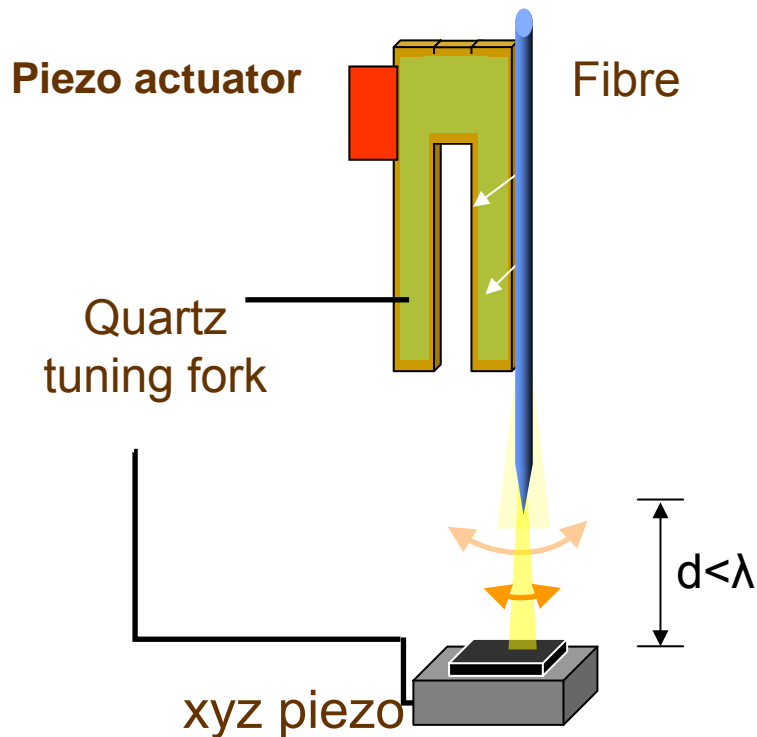
$d \sim \text{nm}$

$F < 10^{-16} \text{ N}$



- Both isolated and conducting surfaces
- Surface topography on atomic scale

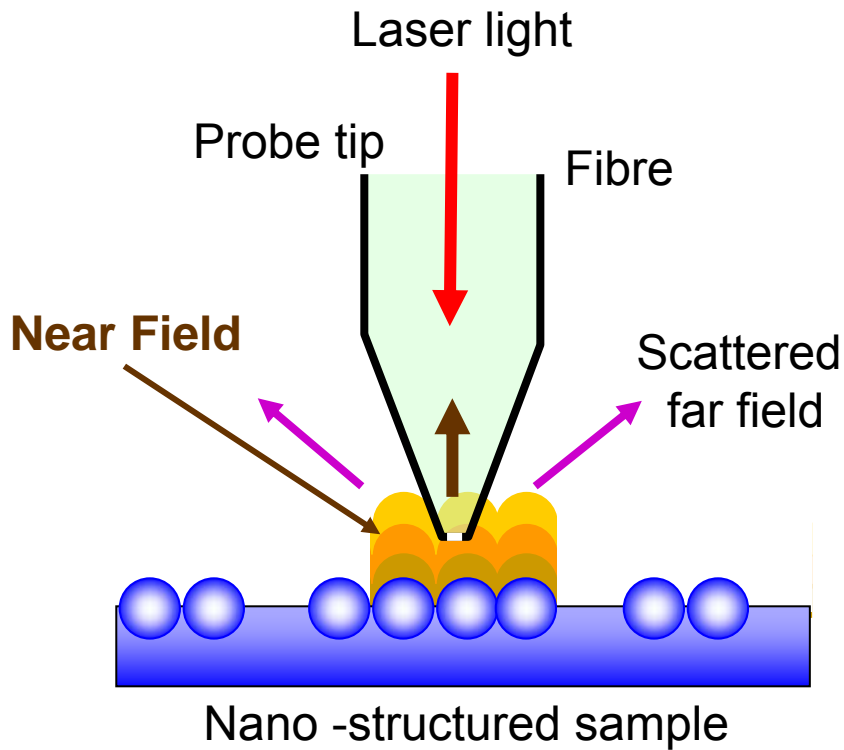
# Scanning Near Optical Microscopy



- The sample is illuminated by light
- The scattered light is collected near the sample by a tapered optical fiber with a sub-wavelength aperture
- Low light throughput
- Resolution limited to  $\lambda/10$
- The tip is kept at a controlled distance from the sample surface by means of a feedback mechanism sensitive to the shear force

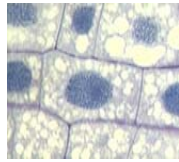
# Scanning Near-field Optical Microscopy

## Aperture technique



- the tip has a sub-wavelength aperture.
- Laser light illuminates the sample through the optical fibre
- it is scattered by the surface and evanescent light is produced
- the aperture picks up the reflecting evanescent light and converts it into propagating light
- which is carried up by the fibre to the detector.

# Resolution of SPM



Plant Cell

Animal Cell

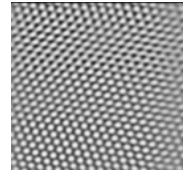
Bacterium

Viral  
ribosome

Protein

Small  
Molecule

Atom



1 cm | 1mm | 100μm | 10 μm | 1 μm | 100nm | 10nm | 1nm | 1Å | 0,1Å

Resolution

0,4-0,7μm\*

10nm

5-2nm

max 0,1nm

Optical microscopy

Electronic microscopy : SEM  
TEM

Scanning Probe  
Microscopy (SPM):

SNOM

AFM

STM

10nm

2Å

0,1Å

\* The diffraction limit depends on used wavelength ( $\lambda$ ).

# Outline

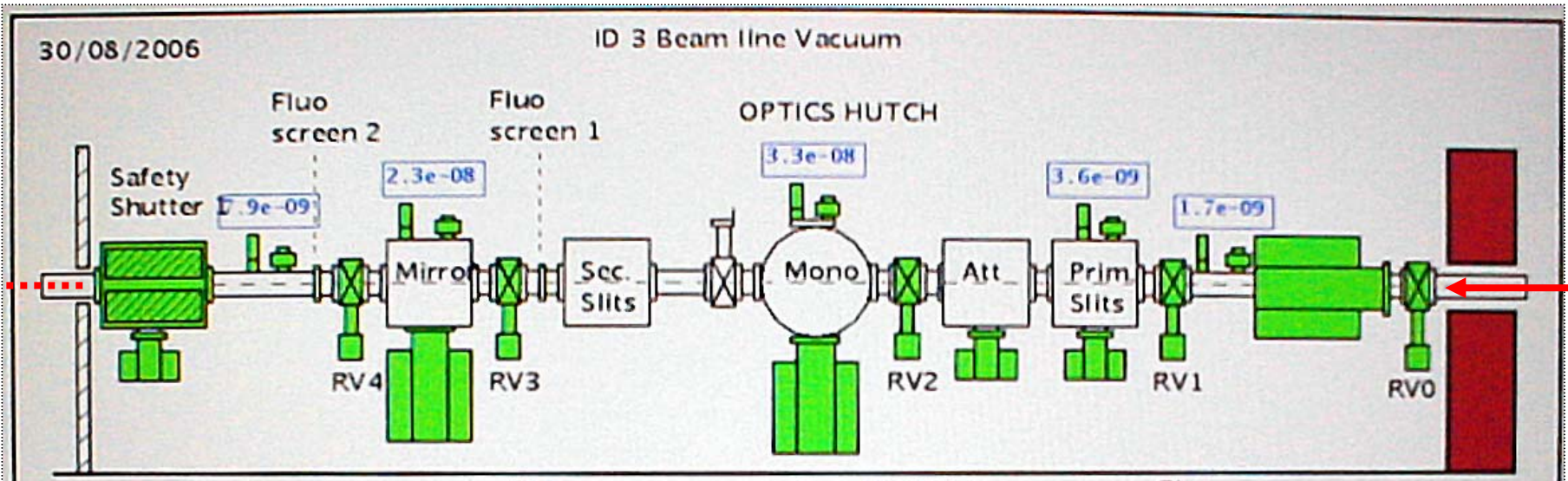
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    - XEOL measurements
  - Conclusions
-

# European Synchrotron Radiation Facility



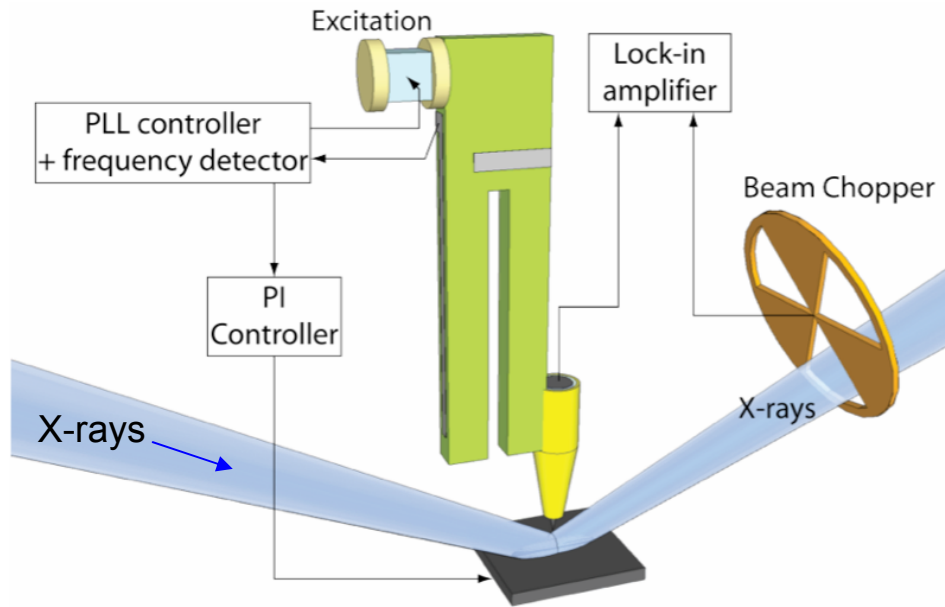


# ESRF ID03 Beamline Layout



Cross section of the beam  $2 \times 2 \mu\text{m}^2$

# XAS – TEY expectancies



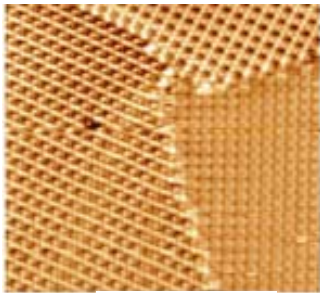
Excitation: X-rays

Measurement: Total electron yield

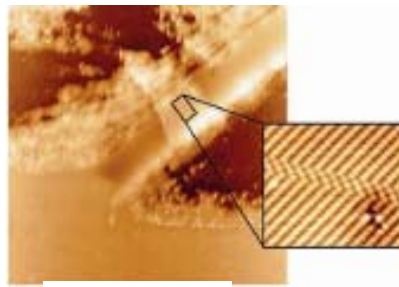
Info: Elemental composition

Chemical state

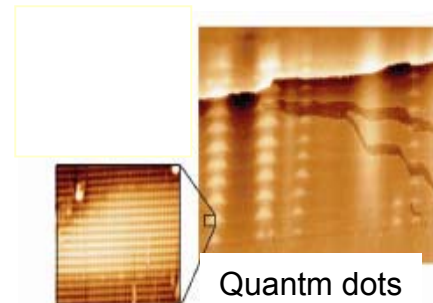
Local structure



2D oxides



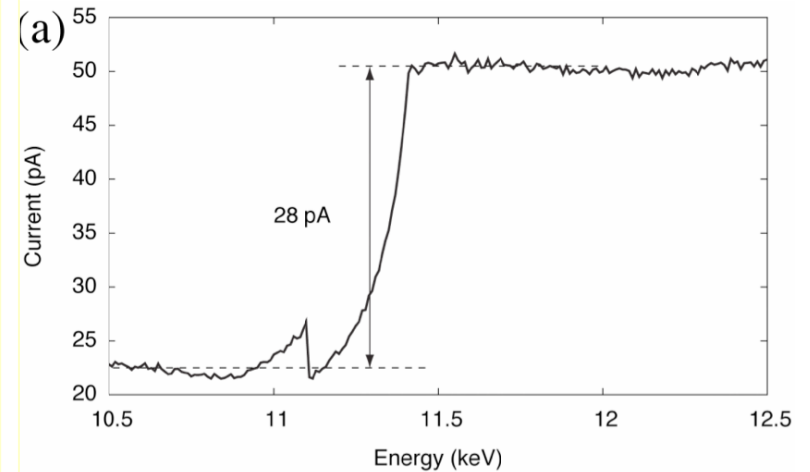
Nanowires



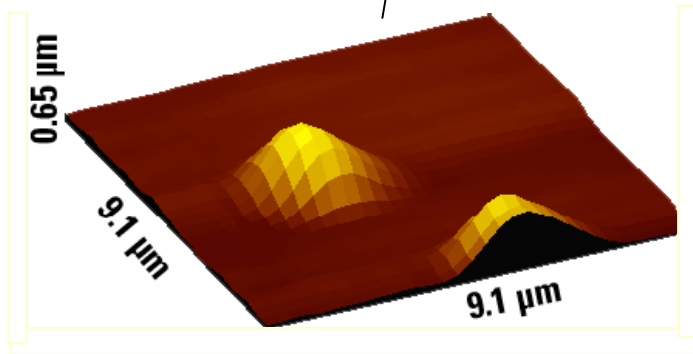
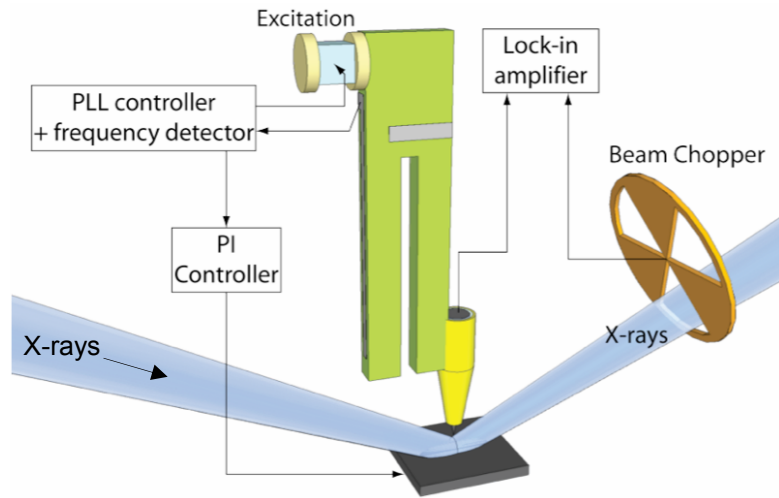
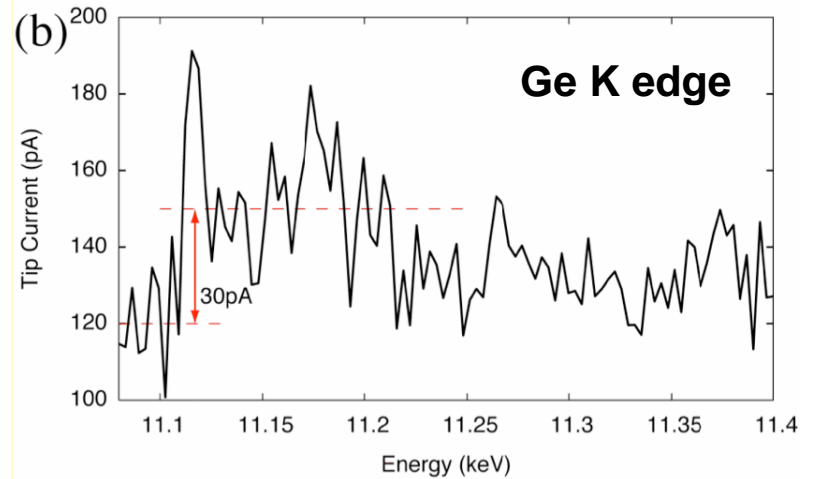
Quantm dots

# XAS-TEY results

## MonteCarlo simulation

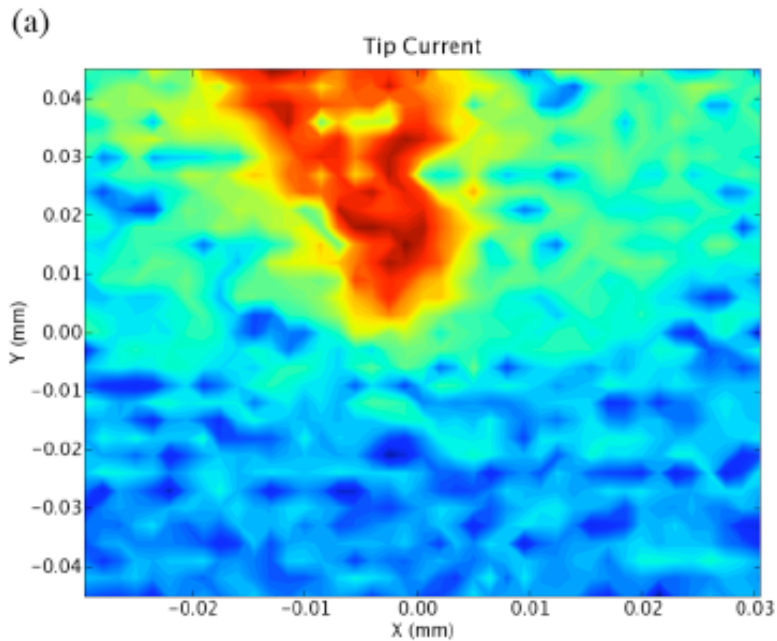


## Experimental result

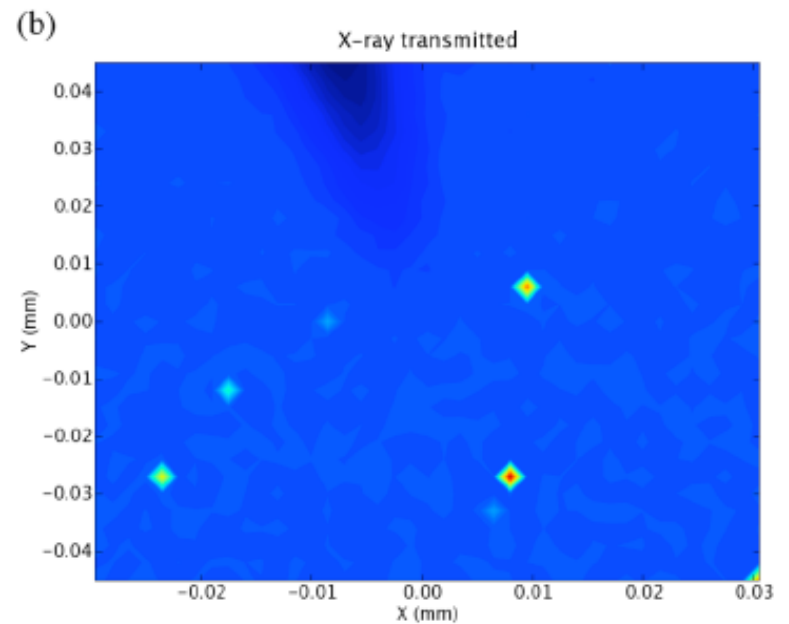


ESRF group

# XAS-TEY results



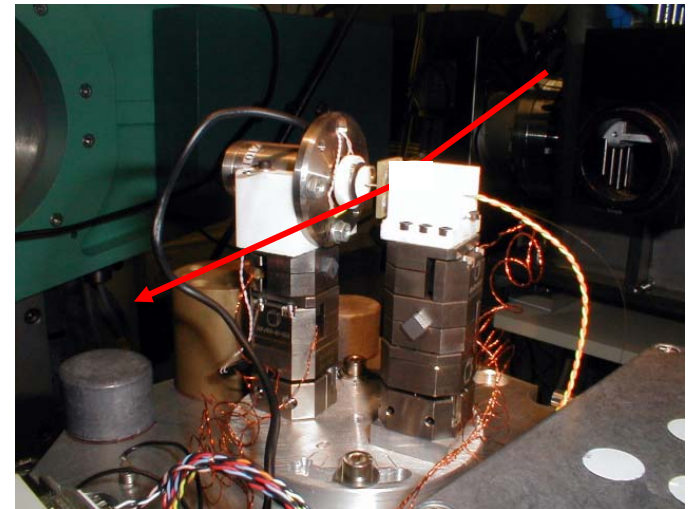
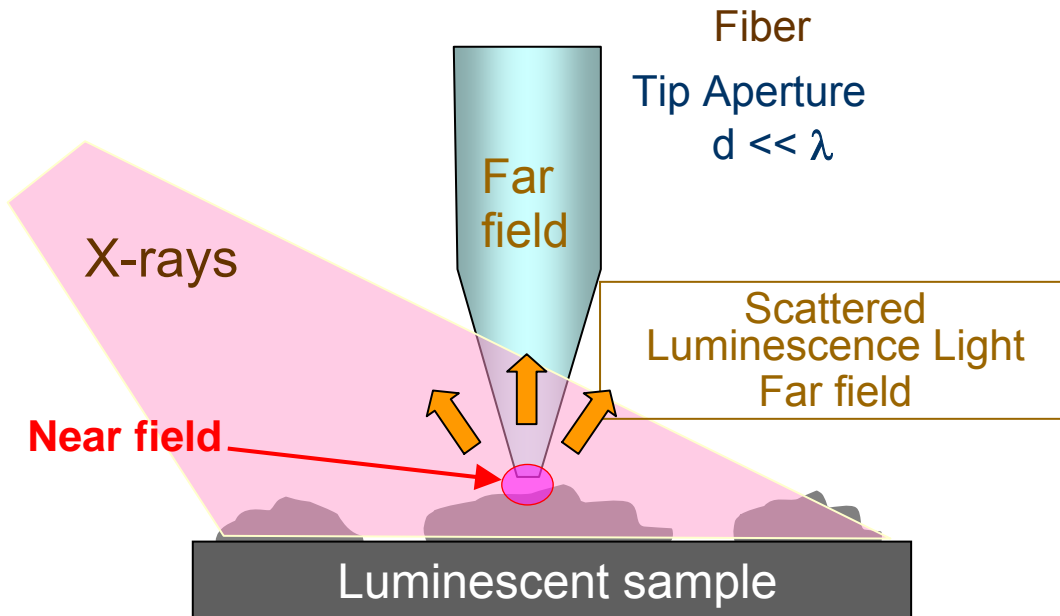
X-Tip current density



Absorption measurement  
in transmission mode

ESRF group

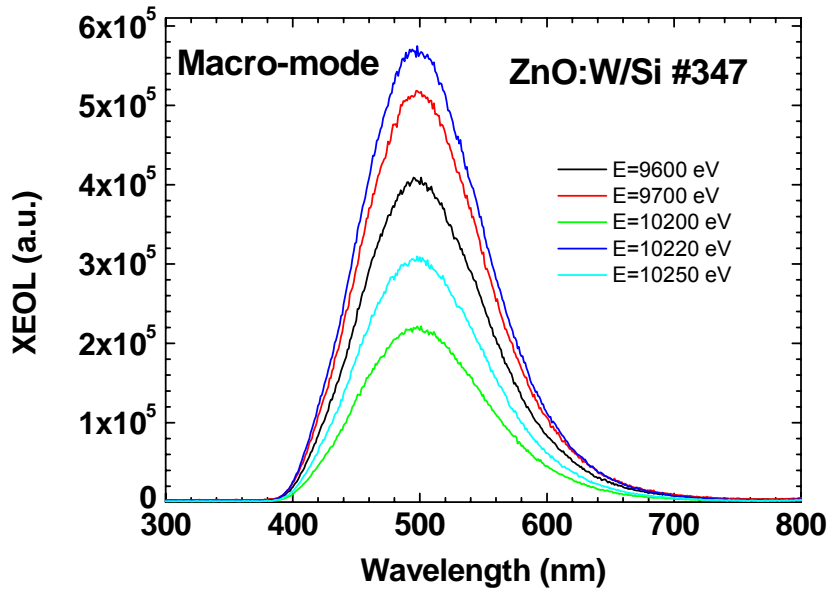
# XAS - SNOM



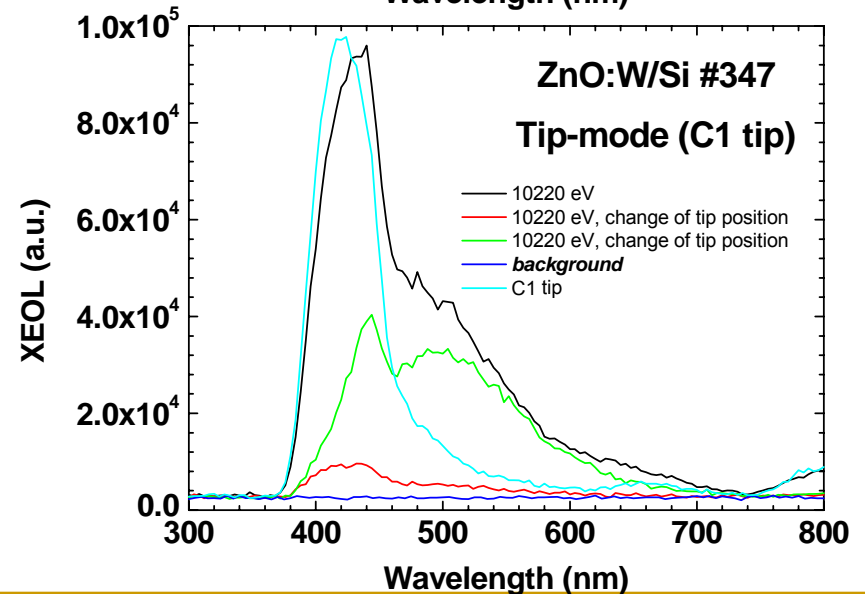
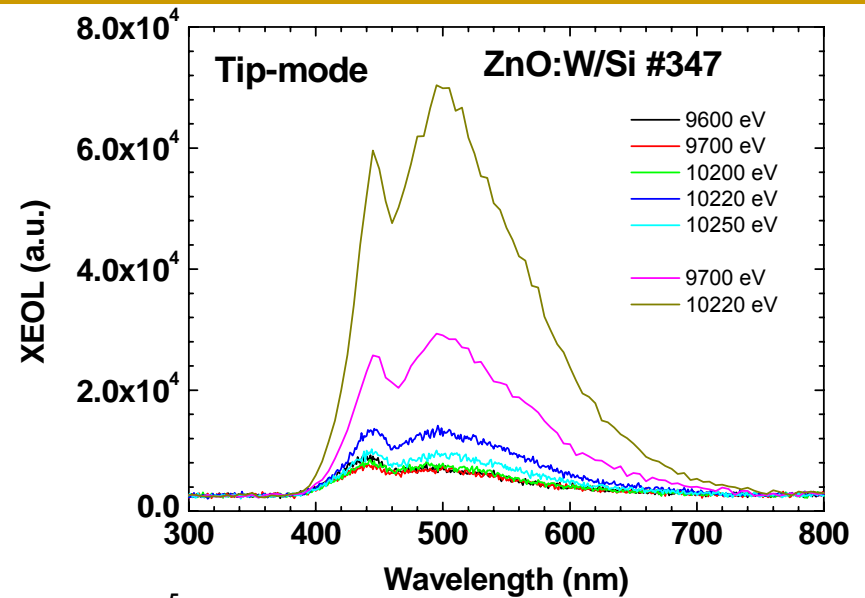
*Prototype made  
by the Marseille group*

Trento- Marseille-Riga group

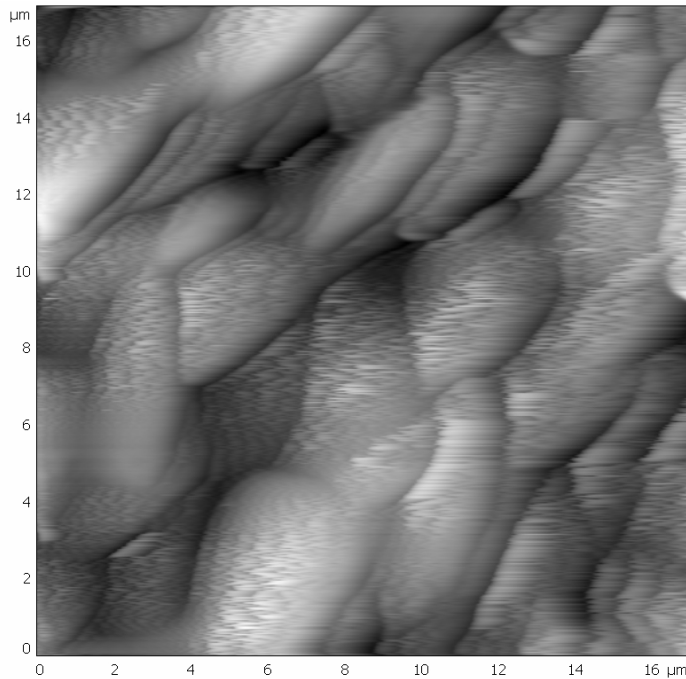
# Thin film ZnO:W/Si



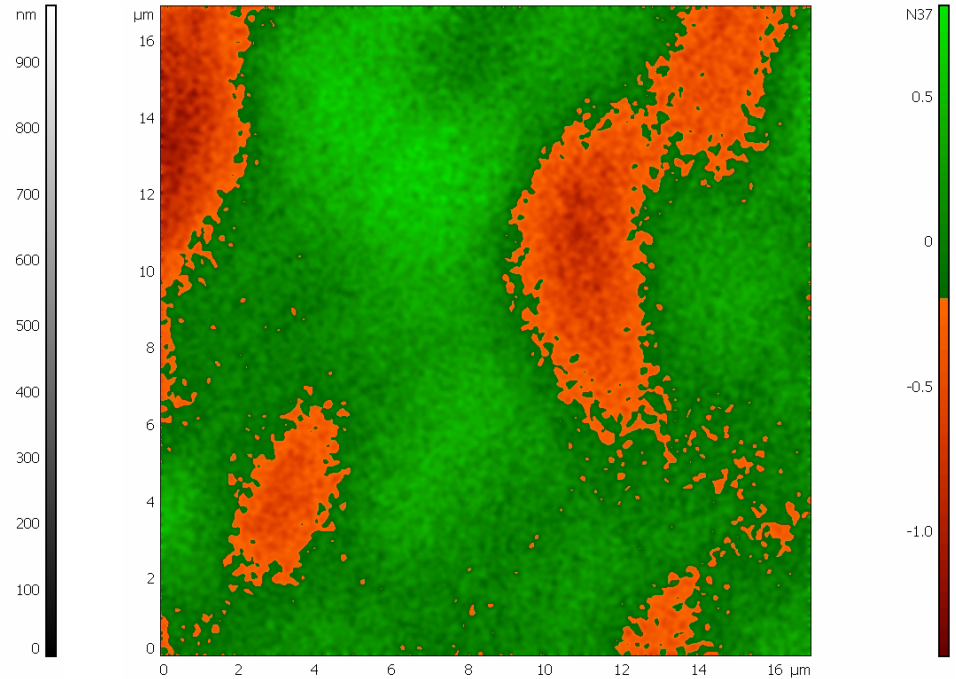
Without the tip



# Thin film ZnO:W/Si



Topography  
in share-force mode  
(17 μm × 17 μm)

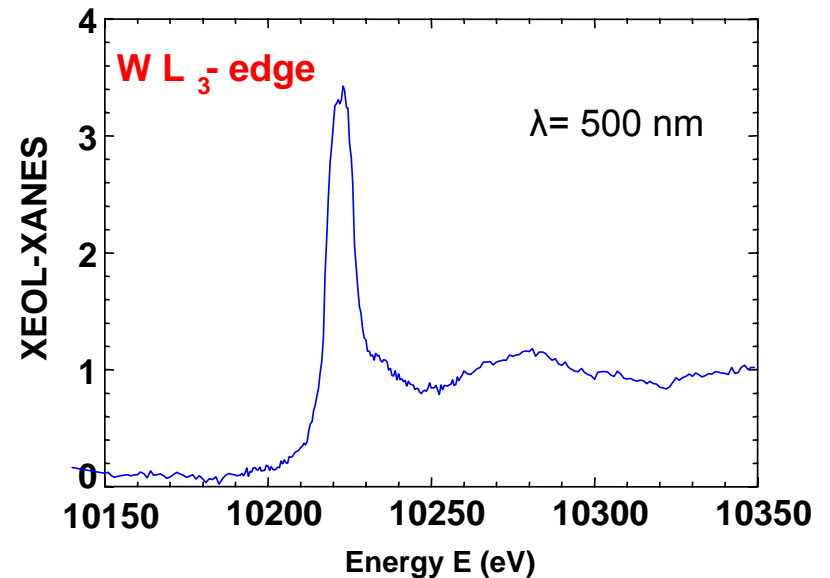
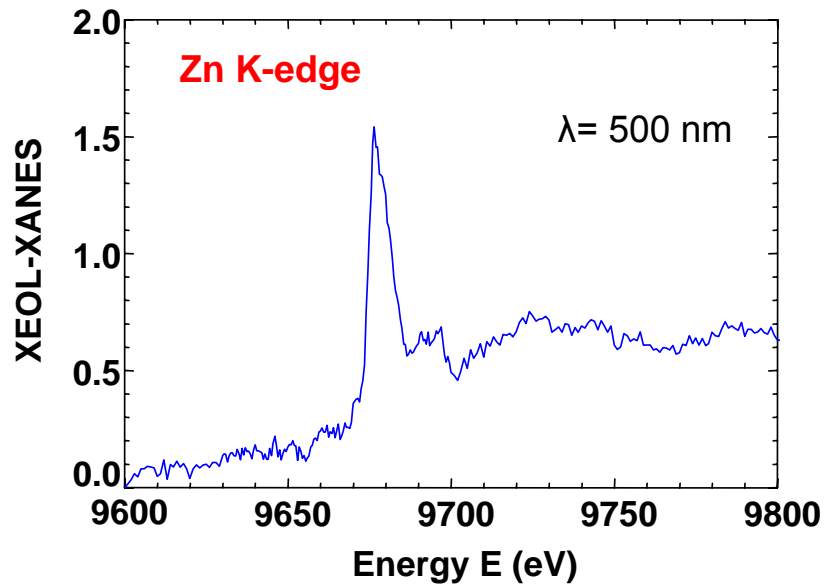


XEOL signal excited at  
the W L<sub>3</sub>-edge “white-line” maximum  
(10222 eV)

**Red** – tungsten rich regions

# Nano-XANES measured by the SNOM tip

## Thin film ZnO:W/Si





# Conclusions

## ACHIEVEMENTS

1. X-TIP prototype is working.
2. It is possible to perform *simultaneously* topography and XEOL scanning and to detect the contrast in XEOL signal due the absorption edges of different materials.
3. It is possible to measure XANES by keeping the tip in a fixed point at the sample surface.
4. It is possible to have a map of the elements present in the nanoparticles

# Conclusions

## What still to do ?

To reduce mechanical vibrations

To avoid tip photoluminescence under x-rays

To improve the quality of tips in order to reach a better lateral resolution in XAS-XEOL mode

To use low energy synchrotron radiation beam-lines

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# Acknowledgements

To all the members of the X-tip group

Grenoble

Marseille

Riga

Tartu

In particular to

Dr. Alexei Kuzmin

Dr. Francesco Rocca

Silvia Larcheri

Many thanks to you for your attention

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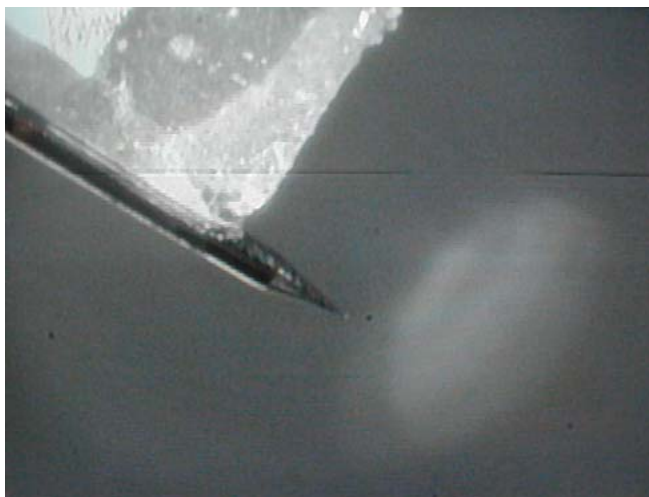




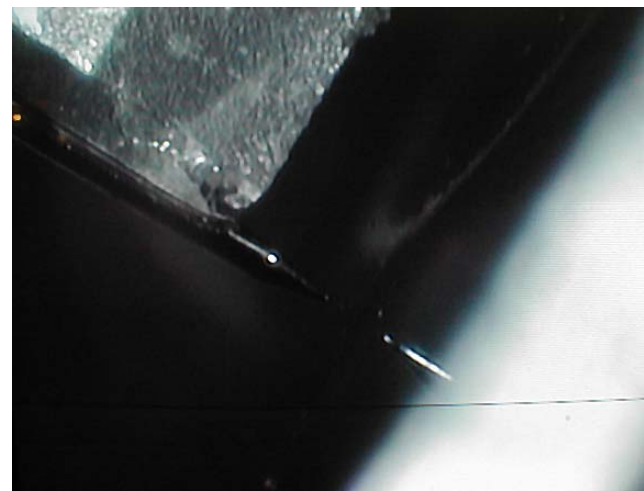




# SNOM Tips



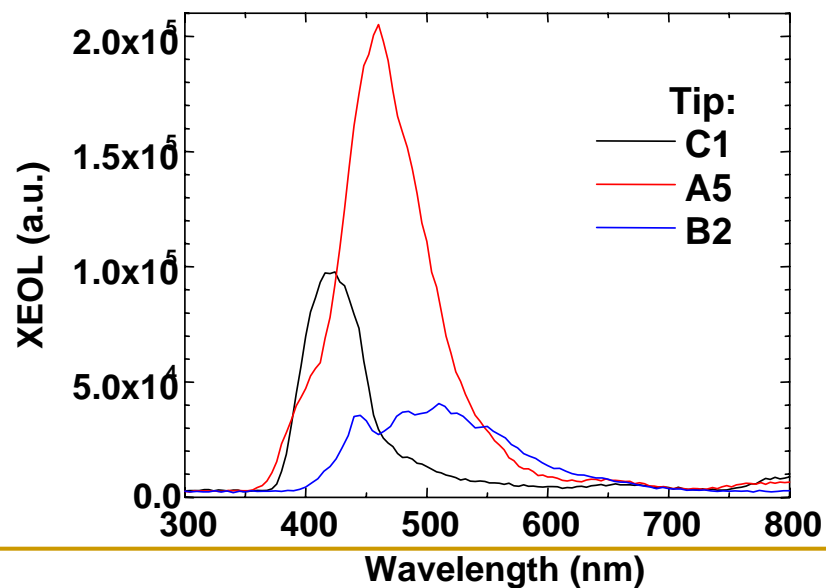
TIP on piezo-fork



Approaching the sample surface

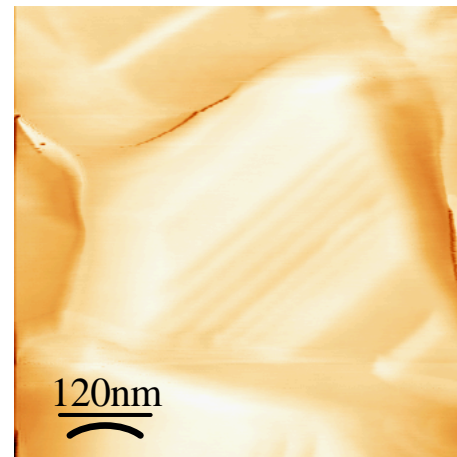
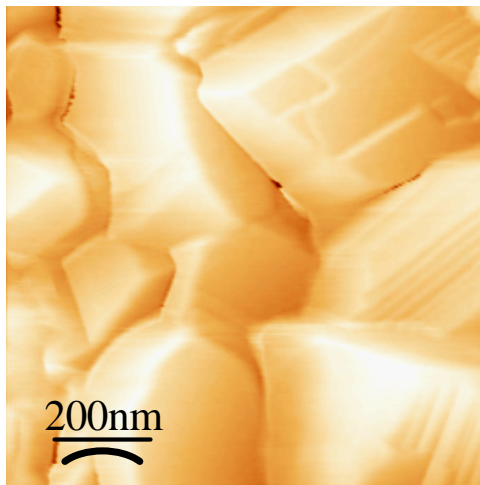
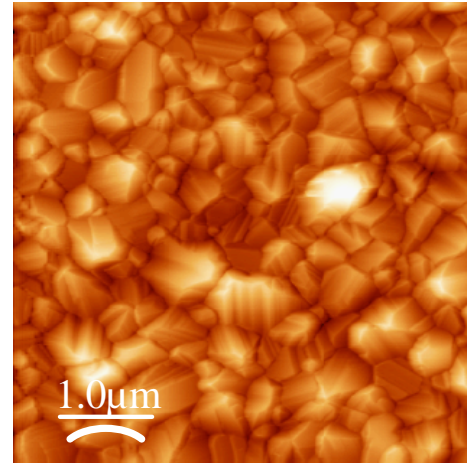
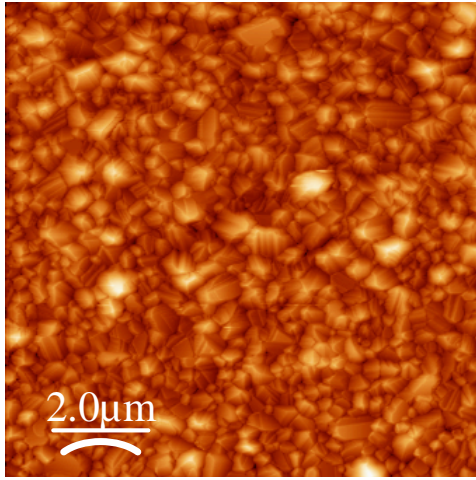


Under the x-ray beam



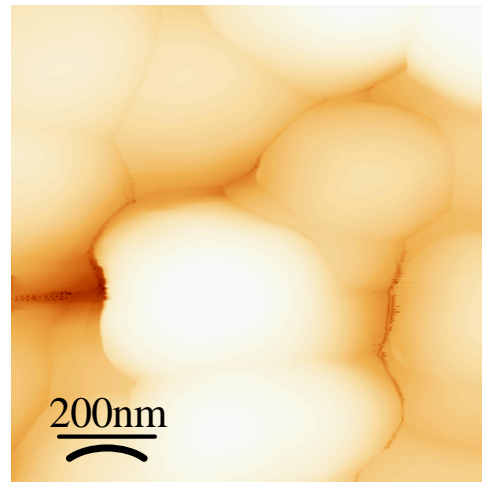
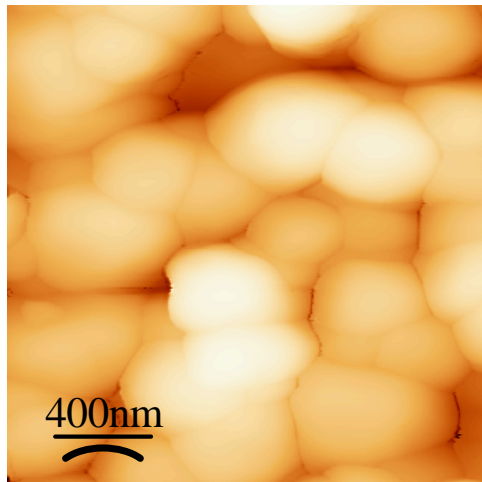
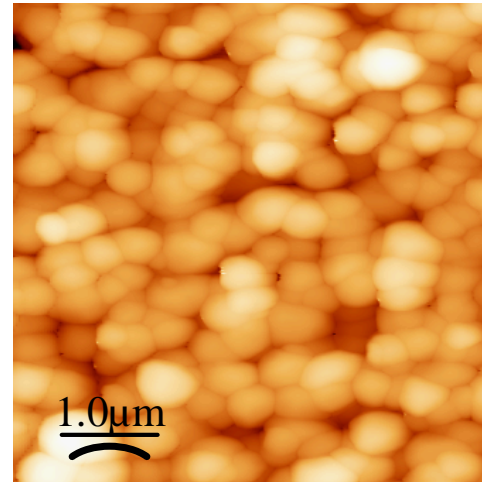
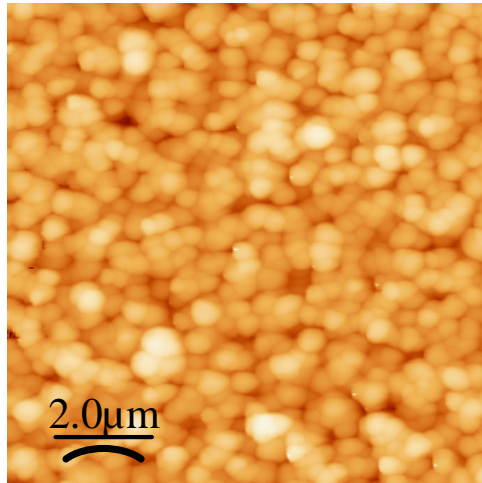


# AFM: ZnO/Si 341HT



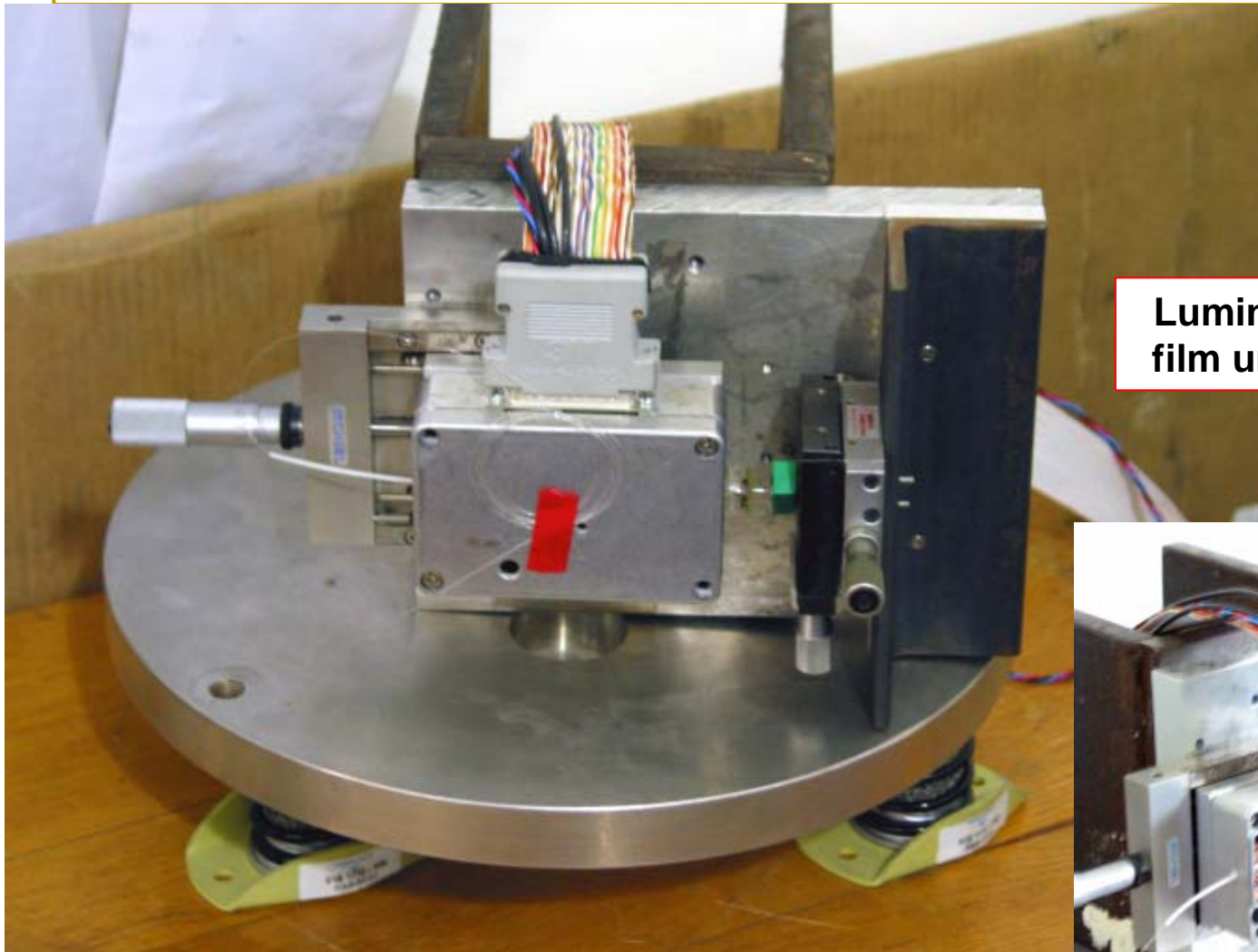
***produced by oxidizing metallic Zn film***

# AFM: ZnO/Si



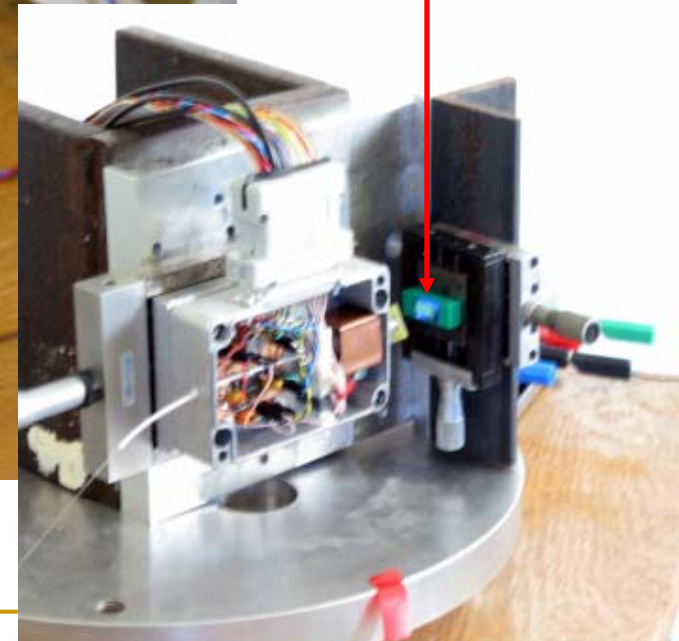
*produced by sputtering in Ar-O<sub>2</sub>*

# SNOM setup at Marseille University

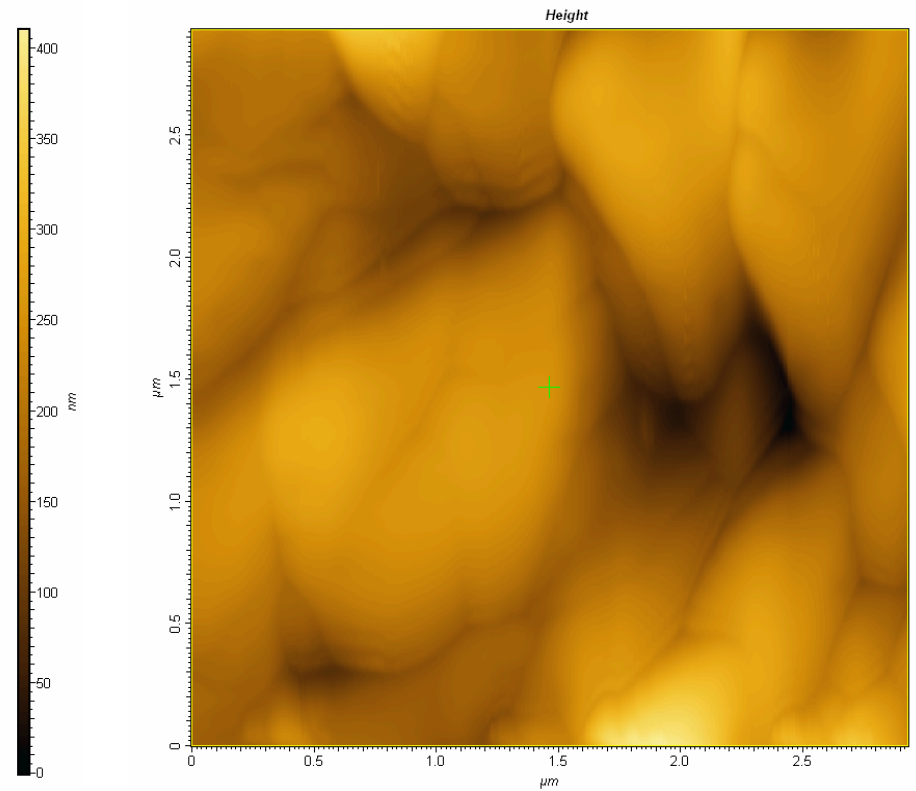
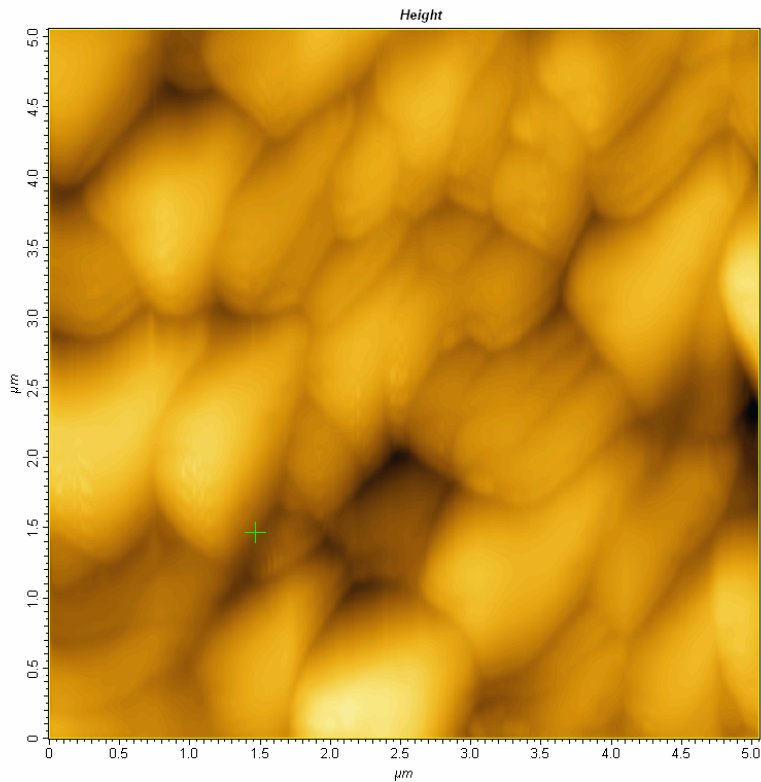


First prototype with *LovaLite* fiber

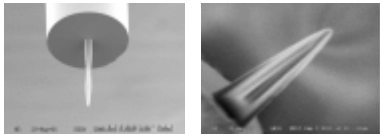
Luminescence of ZnO thin film under laser irradiation



# ZnO/Si – SNOM image by *LovaLite* fiber



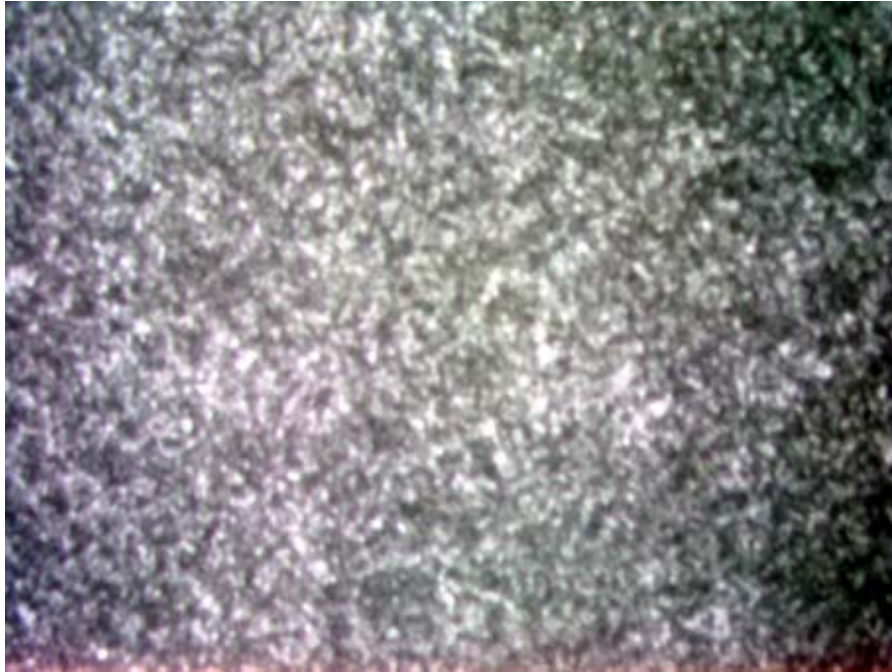
*produced by oxidizing metallic Zn film*



**LovaLite<sup>®</sup>**  
[www.lovalite.com](http://www.lovalite.com)

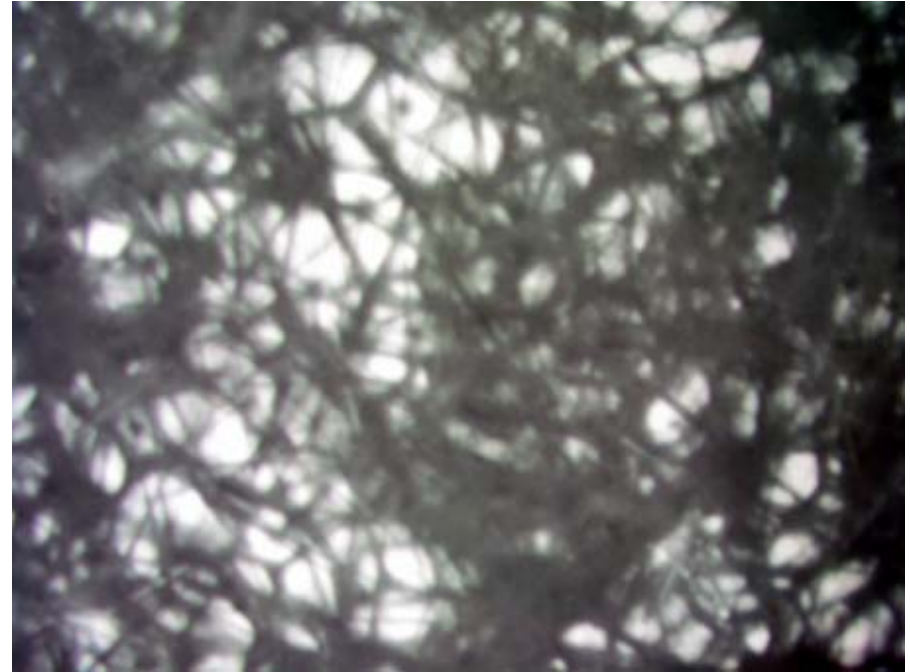
# Optical microscopy of ZnO/Si thin films

produced by magnetron sputtering and atmospheric pressure chemical vapor deposition



**ZnO/Si 341HT**

*(produced by oxidizing metallic Zn film)*

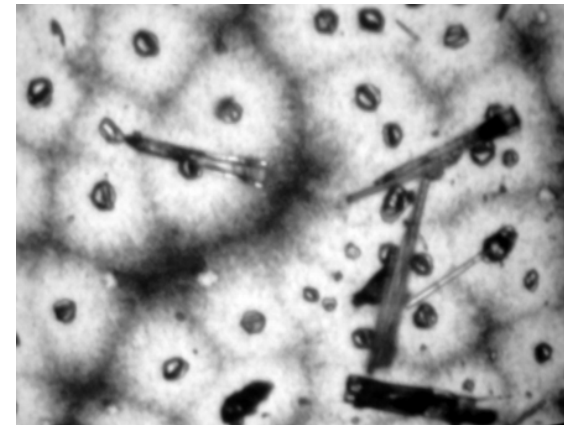
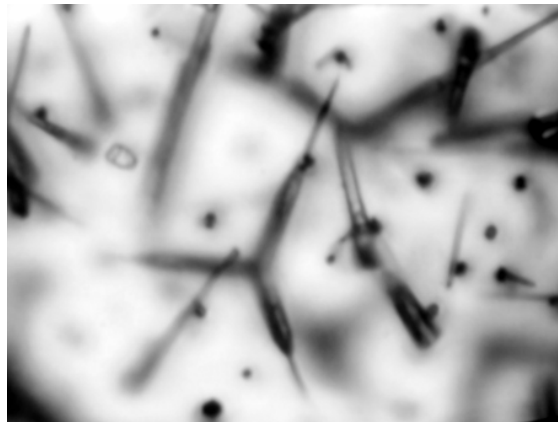
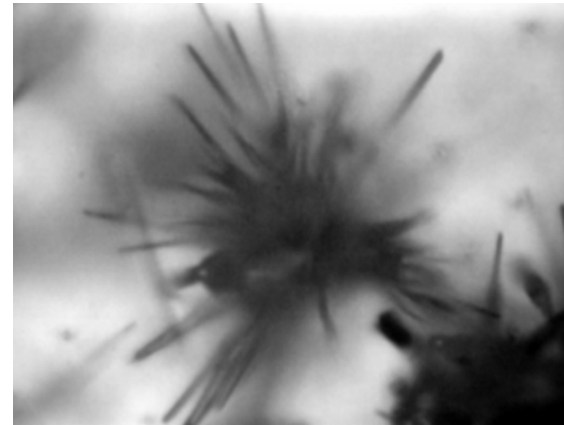
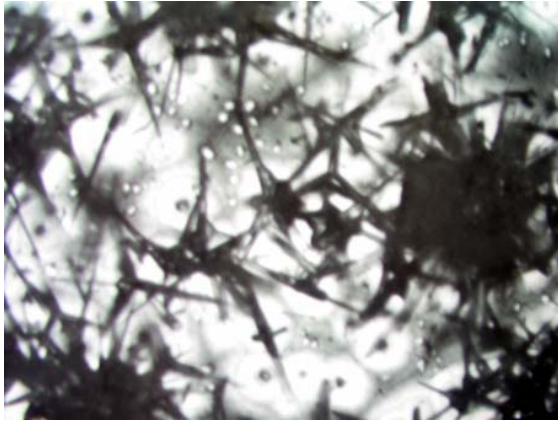


**TEC sample**

*(produced by atmospheric pressure chemical vapor deposition (APCVD) )*

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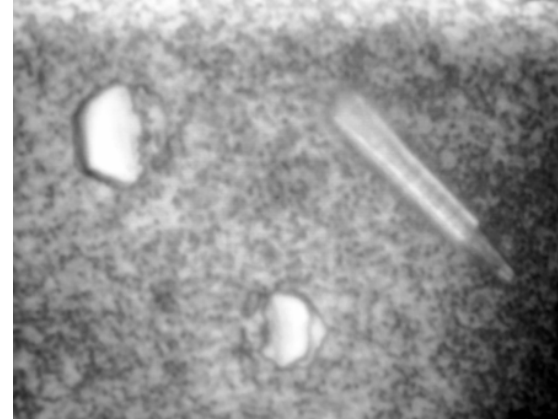
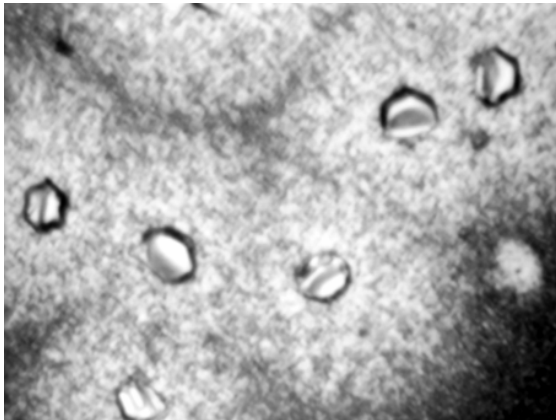
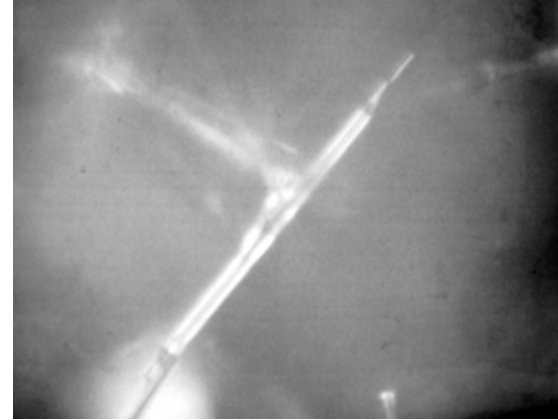
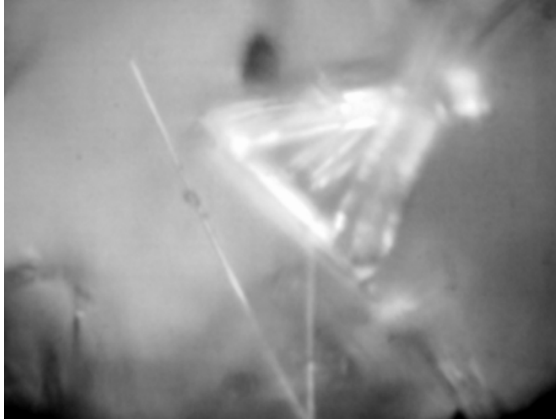
# TEC samples



*produced by atmospheric pressure chemical vapor deposition (APCVD)*

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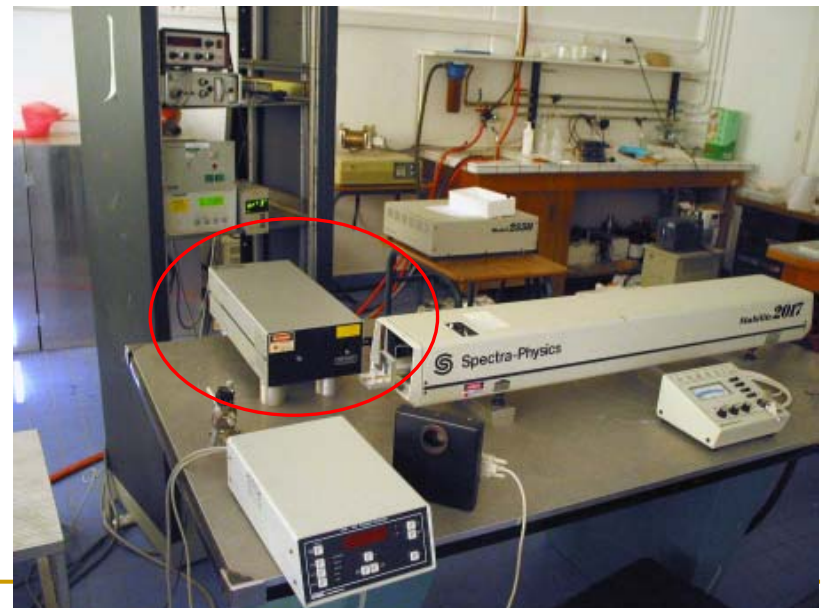
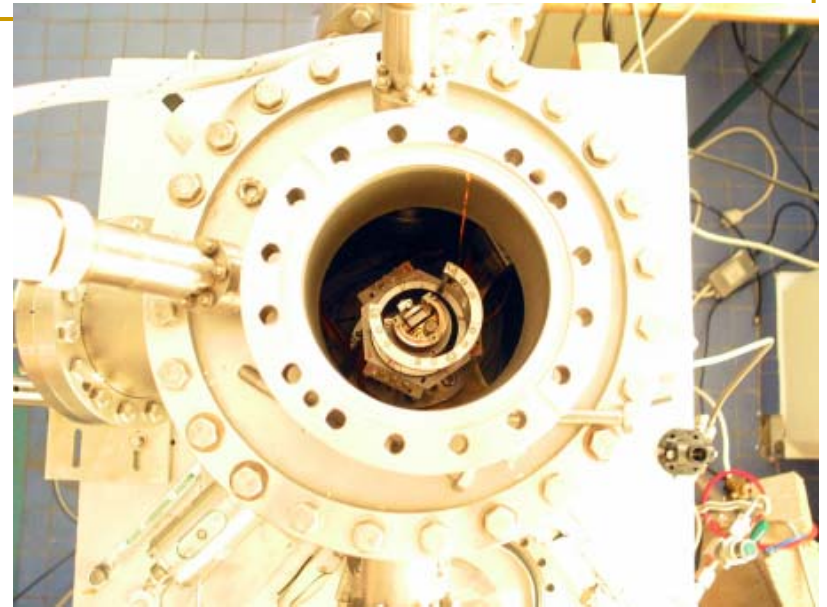
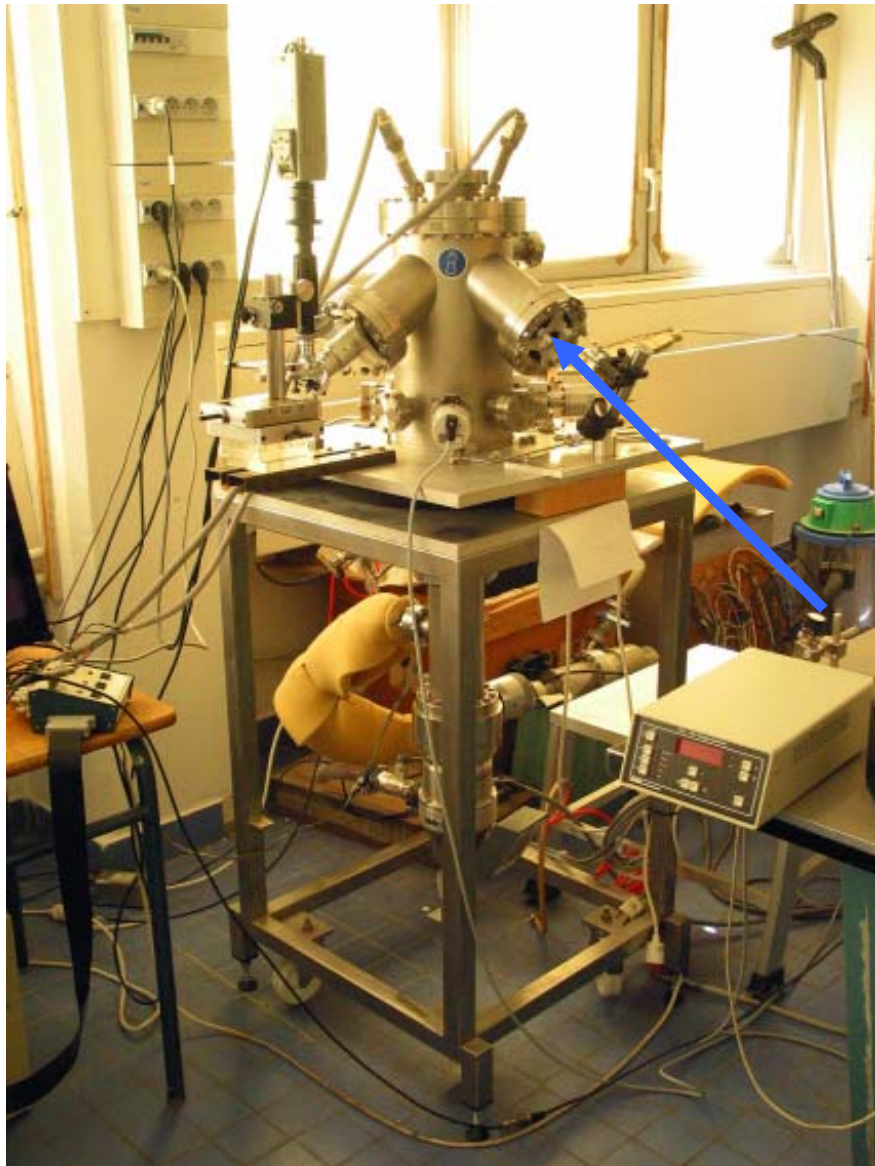
# TEC samples



*produced by atmospheric pressure chemical vapor deposition (APCVD)*

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# STM setup with 350 nm laser excitation source

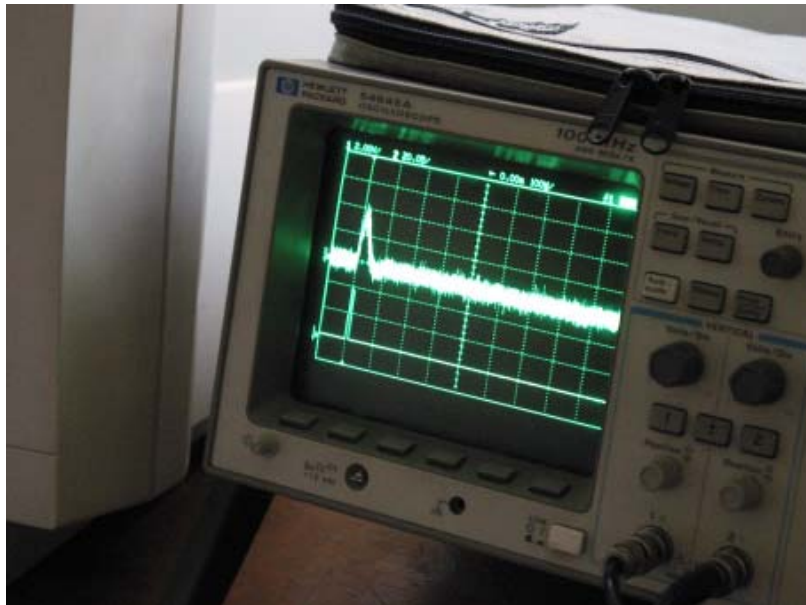
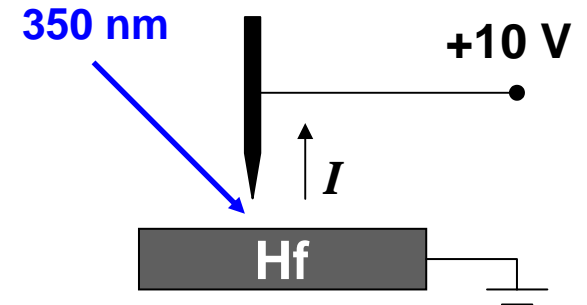
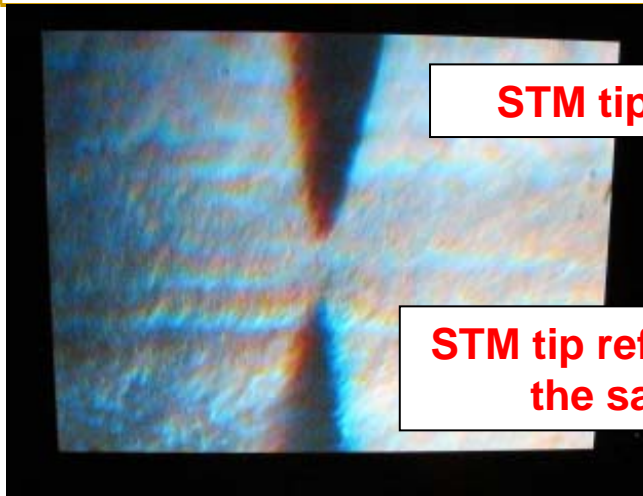




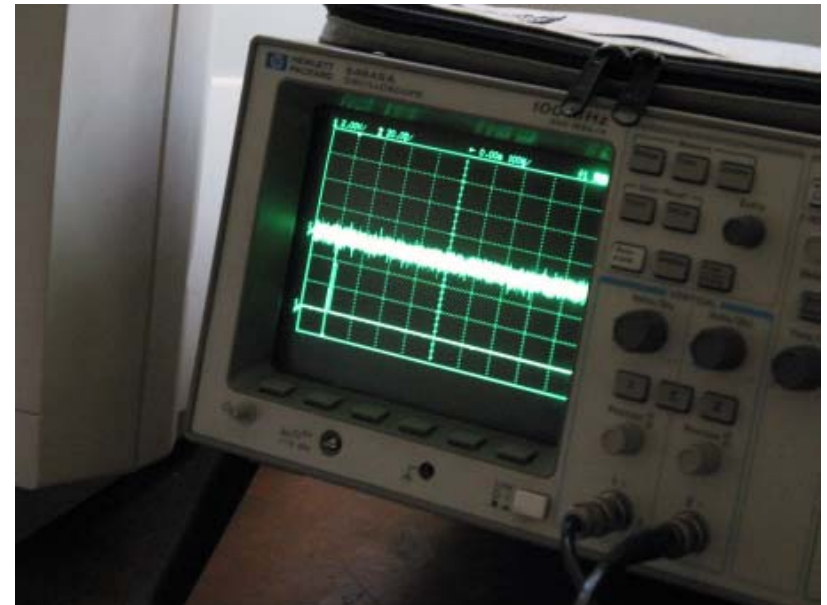
# Sample preparation methods

- "dc magnetron sputtering" in atmosphere of Ar-O<sub>2</sub> using Si substrate and Zn o W as metallic targhets
- 2) tutti campioni TEC fatti con metodo "atmospheric pressure chemical vapor deposition (APCVD)" - analog di CVD ma in aria anche usando Si come substrato (abbiamo scaldato ZnO con grafite fino a ~1100 C),
  - 3) campioni CER sono ceramici - misti dei polveri nano e policristallini,
  - 4) campioni 31-37 fatti attraverso metodo di elettrochimica usando graphite (conduce corente) come substrato/elettrodo e "ZnCl<sub>2</sub> aqueous electrolite solution with Pt as counter electrode".
-

# STM measurement of current under pulsed 350 nm excitation



Laser "ON"



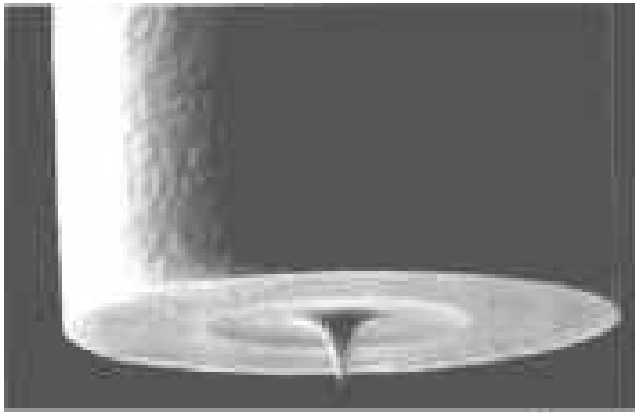
Laser "OFF"

# X-Tip project participants

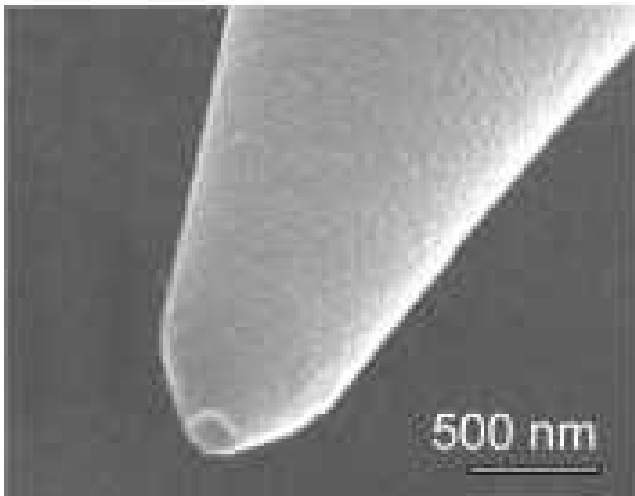


1. **ESRF** - European Synchrotron Radiation Facility, Grenoble, EU; Dr. Hab. Fabio Comin (co-ordinator)
2. **GPEC/CNRS** – Université de la Méditerranée, UMR 6631 CNRS, Marseille, France; Dr. Daniel Pailharey
3. **ISSP** – Institute of Solid State Physics, University of Latvia, Riga, Latvia; Dr.Hab. Juris Purans
4. **OGG-INFM**, Istituto Nazionale per la Fisica della Materia, Grenoble, Italy; Dr. Roberto Felici
5. **LEPES/CNRS** - Laboratoire d'Etudes des Propriétés Electroniques des Solides, CNRS, Grenoble; France Prof. Joël Chevrier
6. **UNITN** - Department of Physics, University of Trento, Italy; Prof. Giuseppe Dalba
7. **UNITA** - University of Tartu, Estonia: Institute of Physical Chemistry and Institute of Physics of the University of Tartu, Estonia, Dr. Väino Sammelselg
8. **IFN-CNR** - Institute for Photonics and Nanotechnologies, Section "ITC-Cefsa" of Trento, Italy; Dr. F. Rocca.

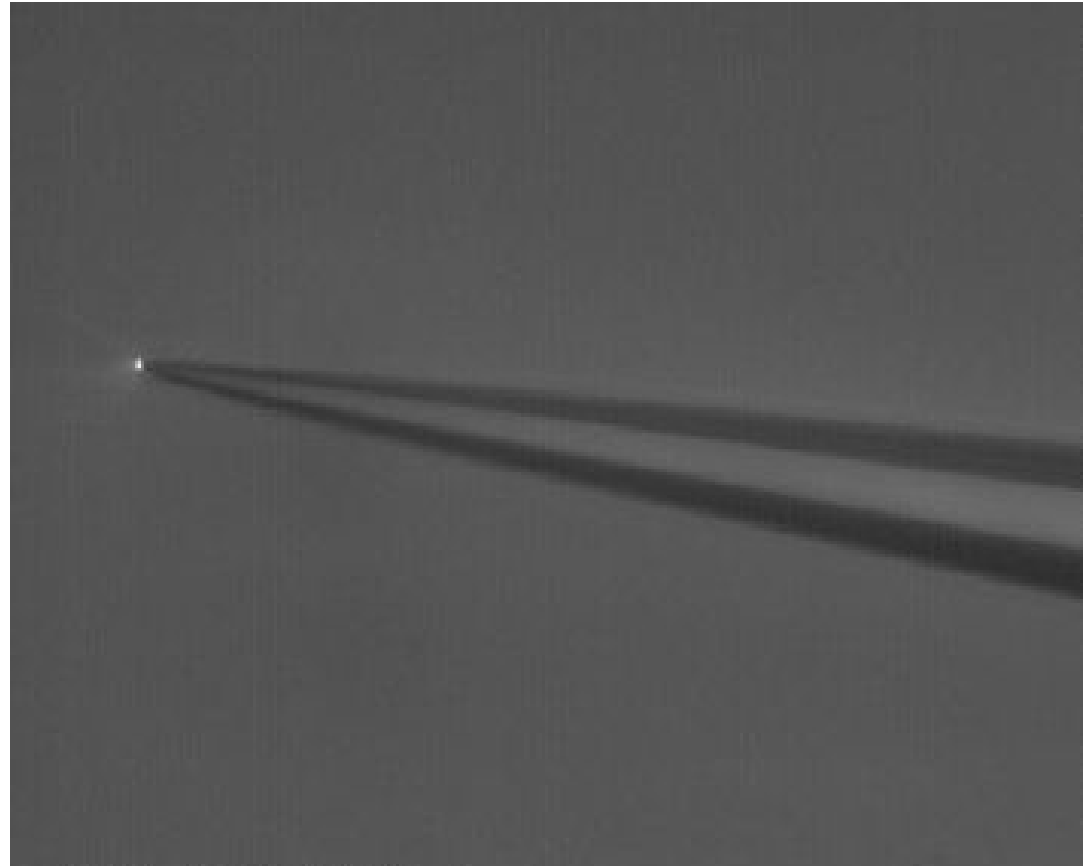
# SNOM Pictures Aperture Probes



5 μm

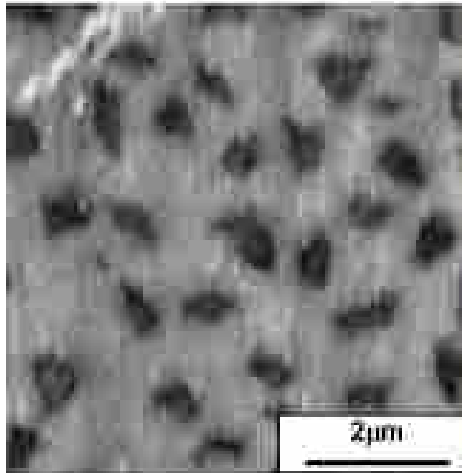


500 nm

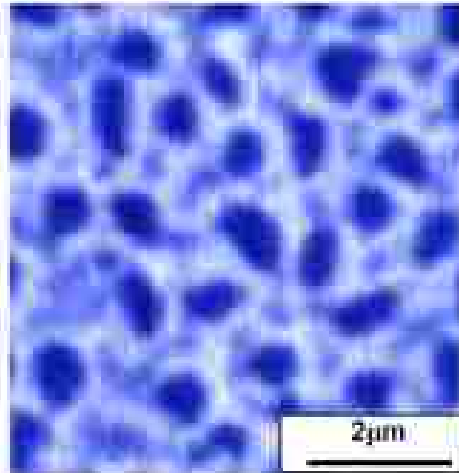


# SNOM : Some images

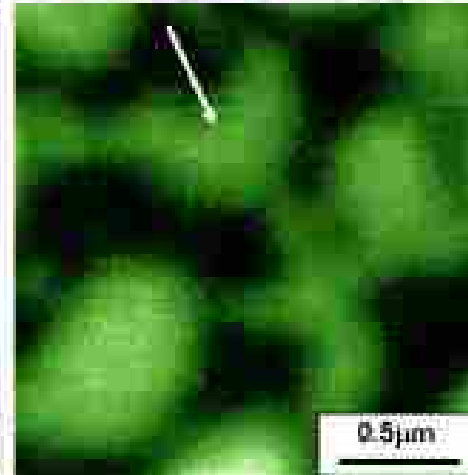
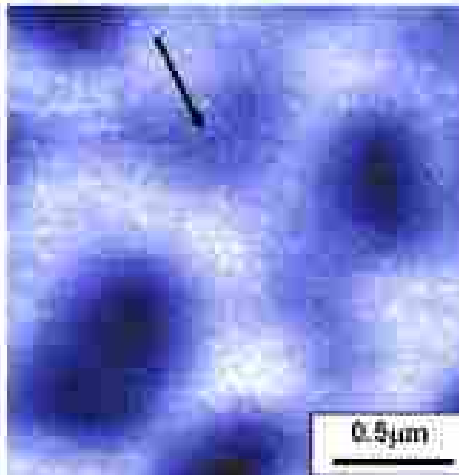
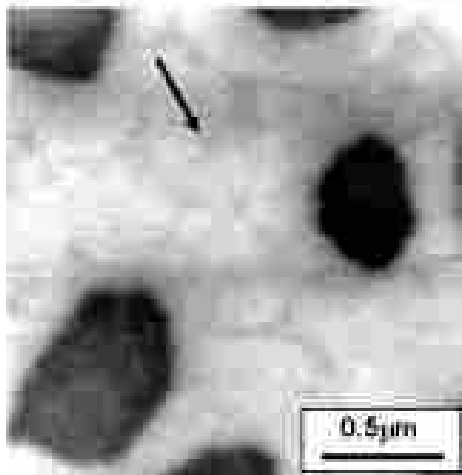
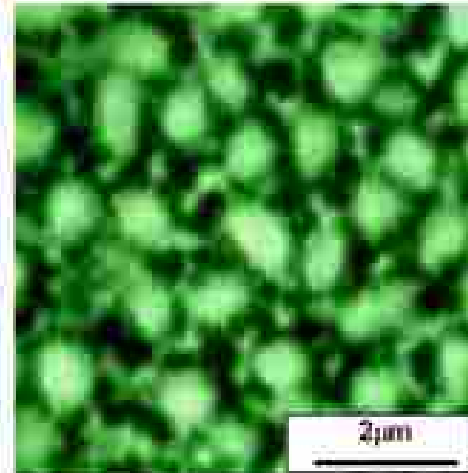
Topography



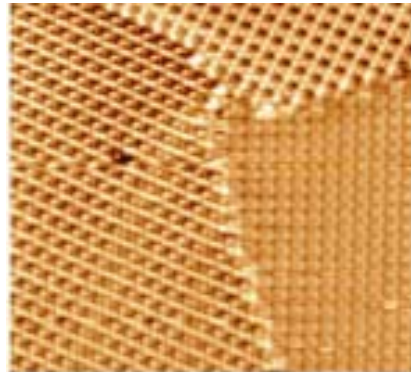
Transmission 488 nm



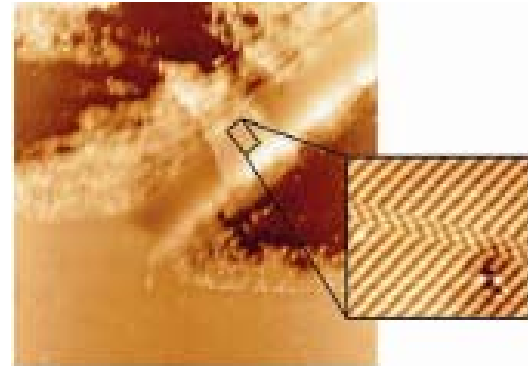
Fluorescence >515 nm



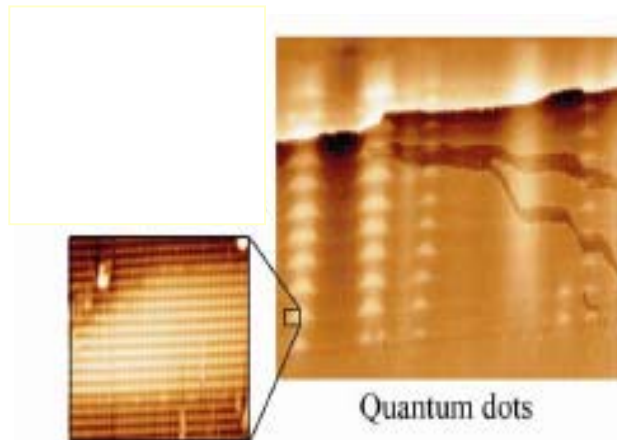
# X-Tip expectances from XAS - TEY



2D-oxides



Nanowires



Quantum dots

Topological structure

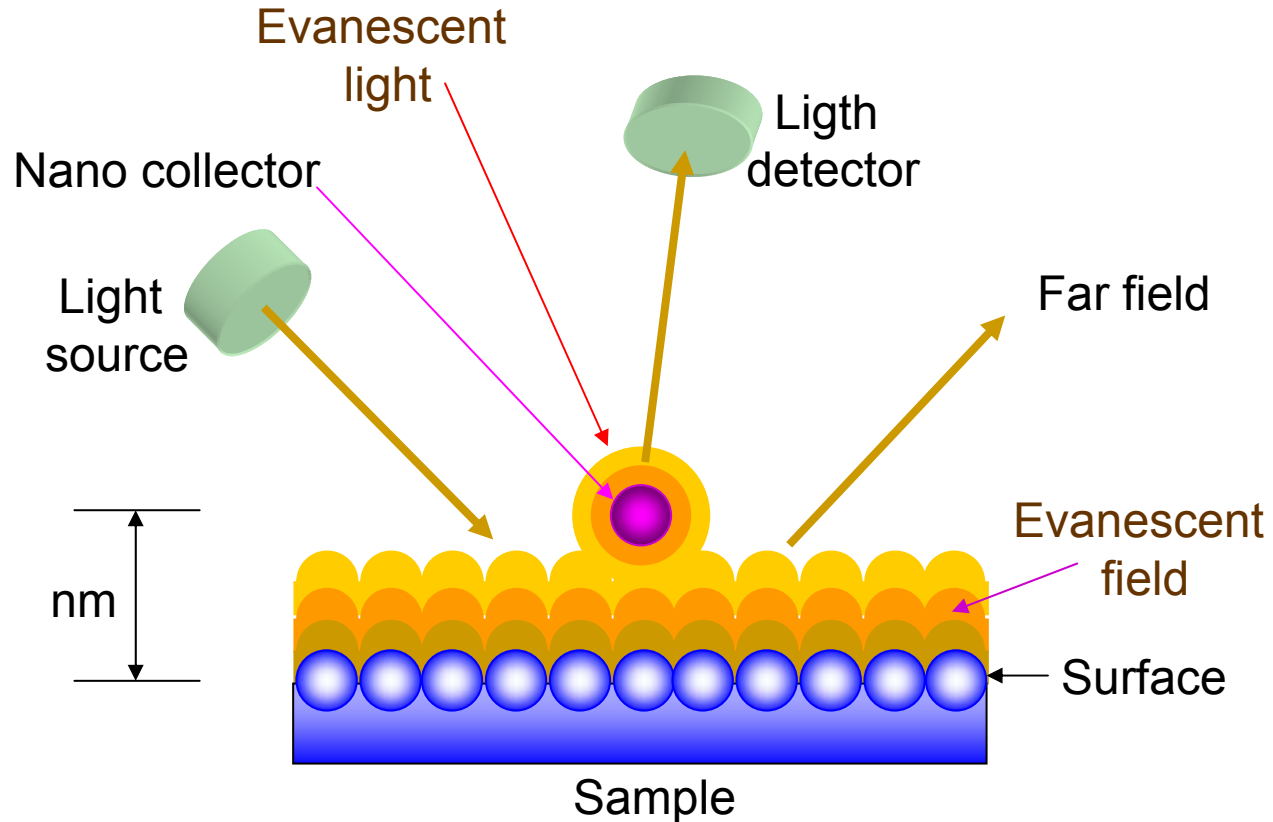
+

Local distribution of elemental constituents

+

geometrical structure and chemical composition of single nanowires and dots

# SNOM: Evanescent Light



The atoms in the probe absorb evanescent photons and re-radiate propagating photons.

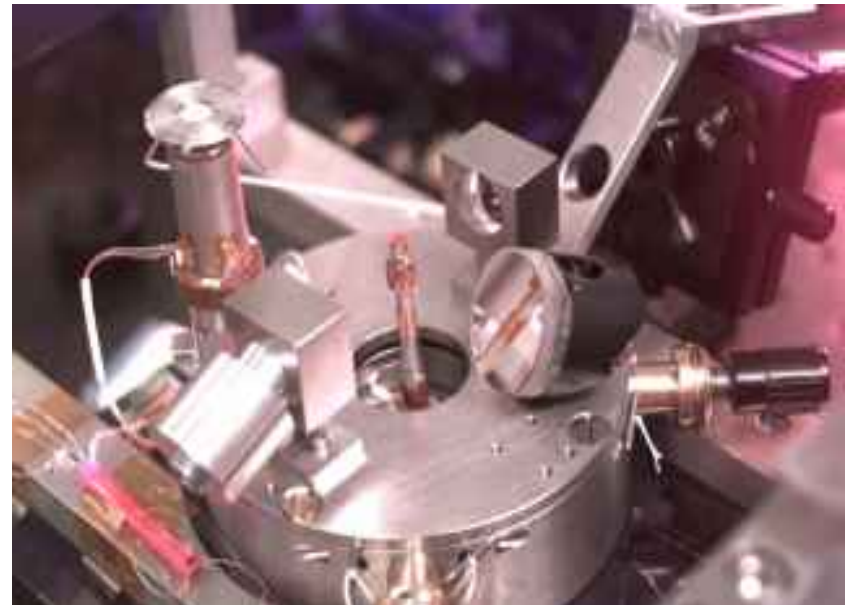
# Conventional Microscopes and SNOM

- Conventional optical microscopes
  - Max  $\sim 1200\times$  magnification
  - Look very different from a SNOM

Conventional Microscope



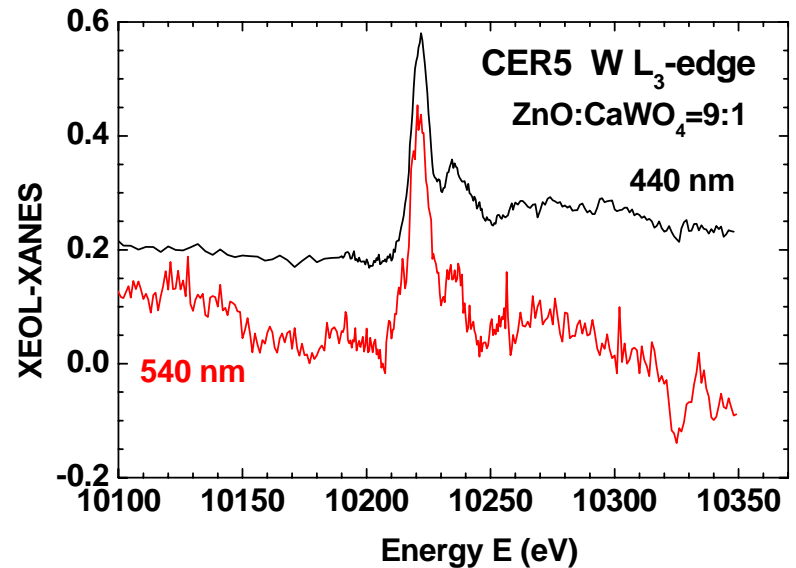
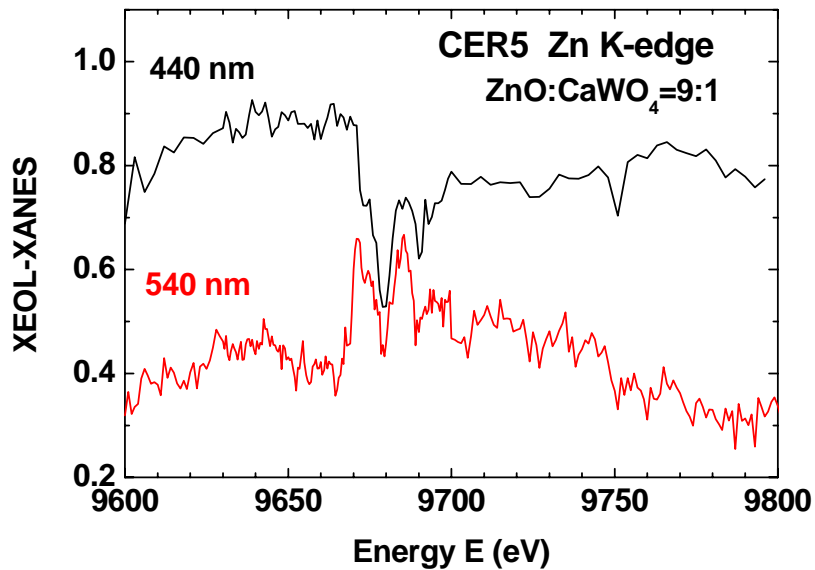
SNOM





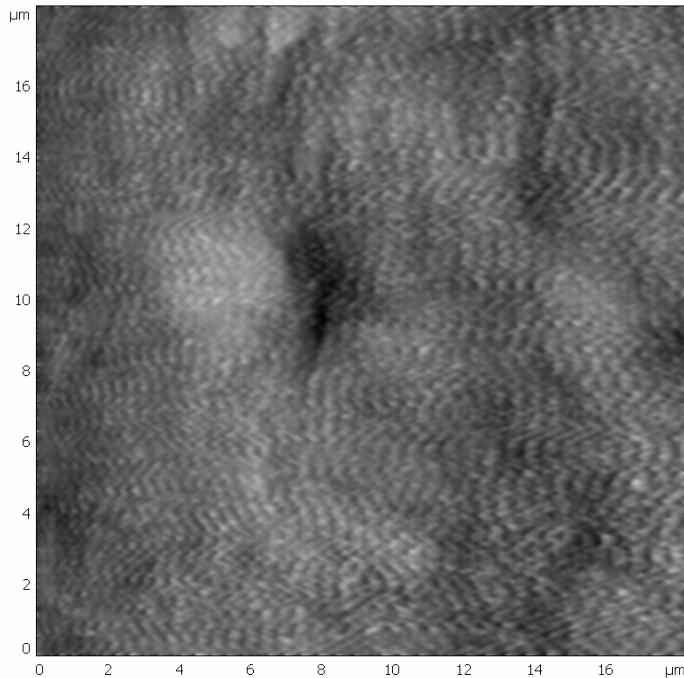
# Mixed ceramics $\text{ZnO}:\text{CaWO}_4=9:1$ (CER5)

Note negative edge !

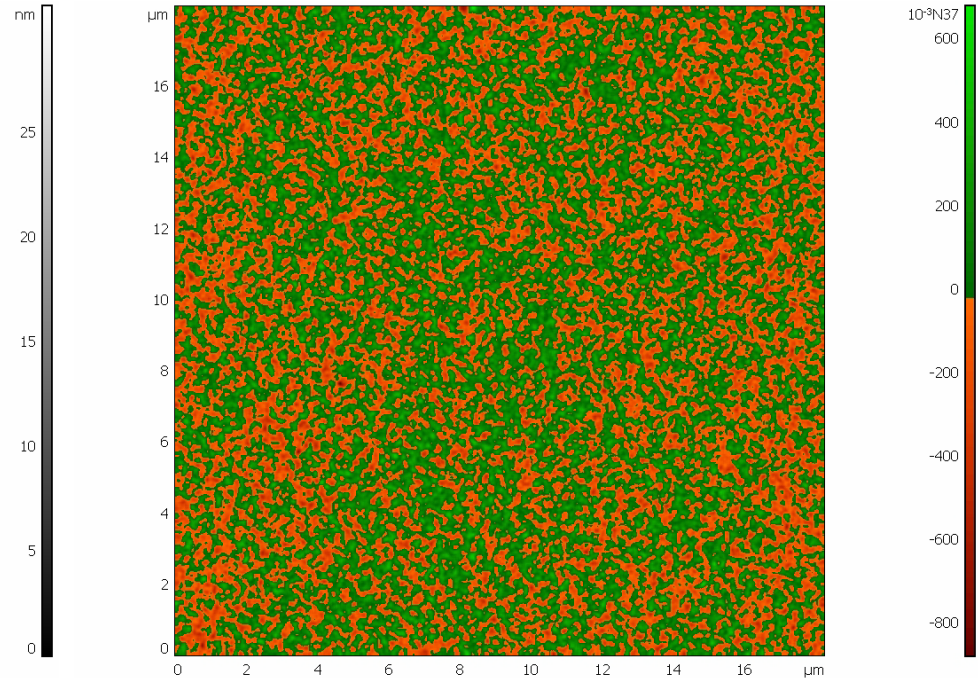


## Nano-XANES measured through the SNOM tip

# Thin film $\text{ZnWO}_4 + \text{ZnO}/\text{Si}$



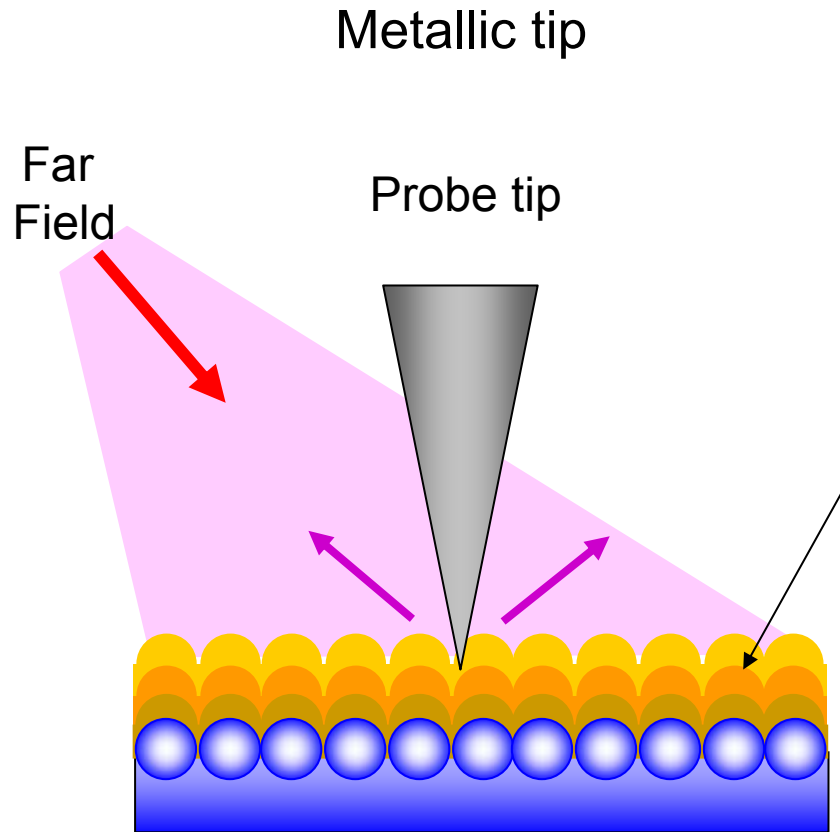
Topography  
in share-force mode  
(18 μm × 18 μm)



XEOL signal excited at  
the W  $L_3$ -edge “white-line” maximum  
(10222 eV)

**Red** – tungsten rich regions

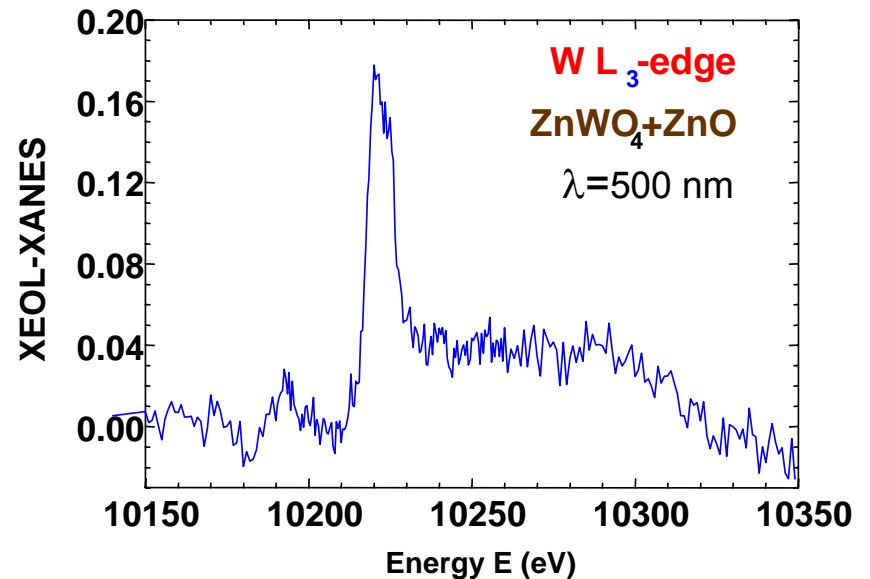
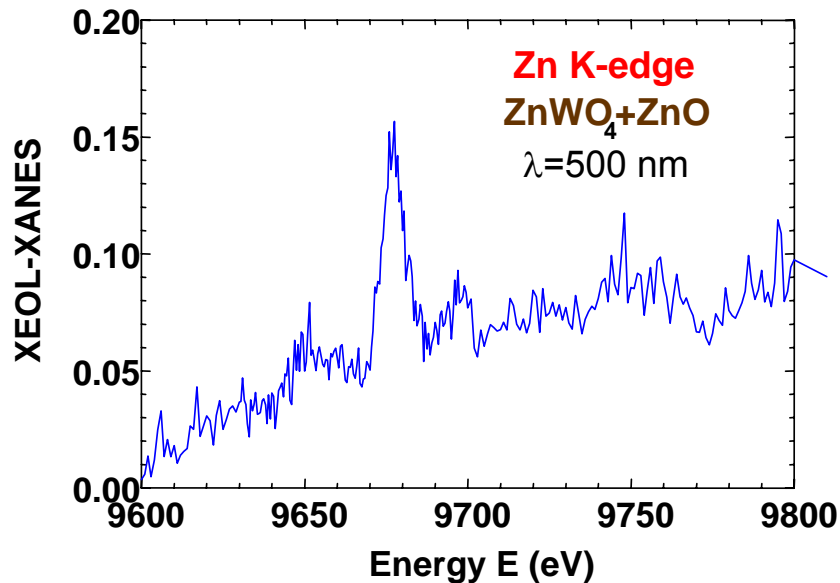
# SNOM: Apertureless technique



The tip is excited by the evanescent field and re-irradiates propagating light

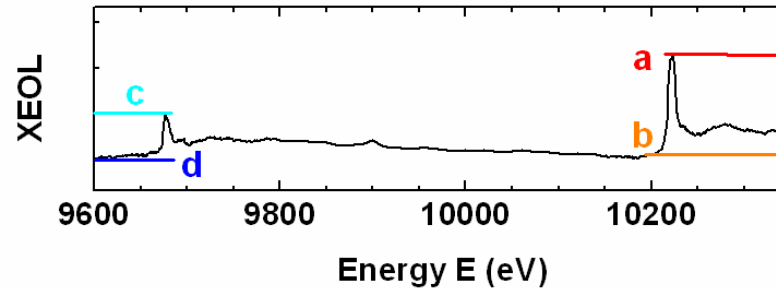
Difficulty to separate re-irradiated light from the light reflected from the surface

# Thin film $\text{ZnWO}_4+\text{ZnO}/\text{Si}$



Nano-XANES measured through the SNOM tip

# Thin film ZnWO<sub>4</sub>+ZnO/Si



*"white-line" maximum*

**Average intensity:**

$$I_e = 0.84$$

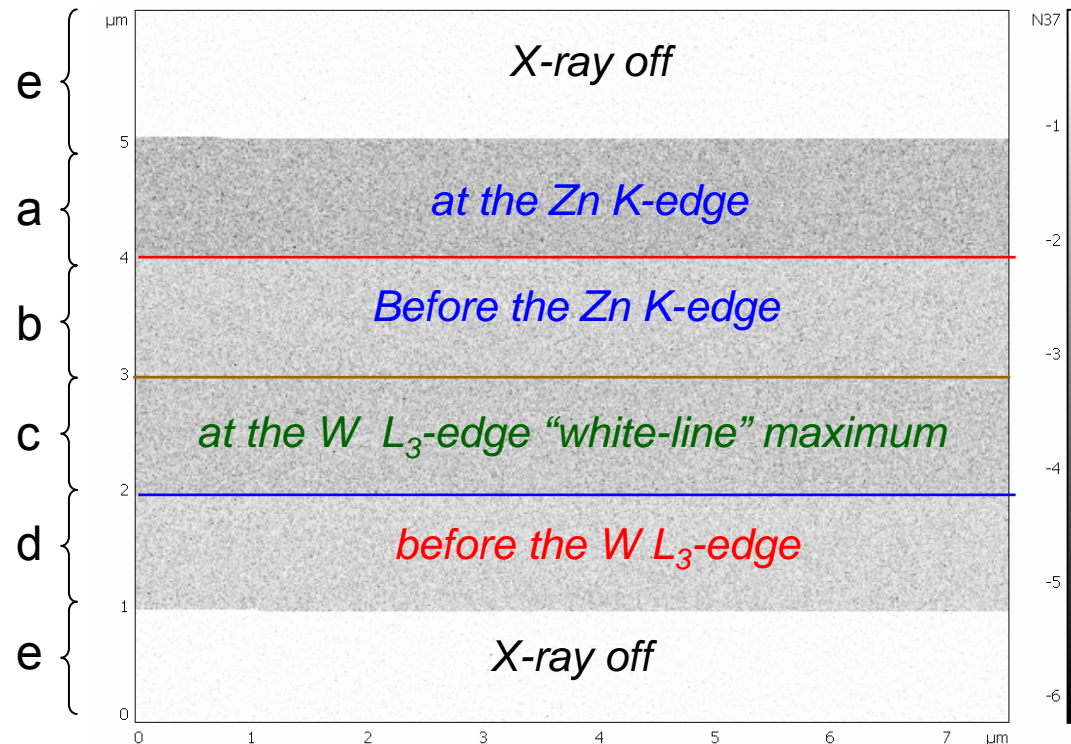
$$I_a = 1.50$$

$$I_b = 1.12$$

$$I_c = 1.30$$

$$I_d = 1.04$$

$$I_e = 0.74$$



# Conclusions

## What still to do ?

To reduce mechanical vibrations

To avoid tip photoluminescence under x-rays

To improve the sensitivity of the photo-multiplier in order to improve the photoluminescence detection

To use low energy synchrotron radiation beam-lines

To improve the quality of tips in order to reach XEOL the lateral resolution

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